



# BIPOLAR ANALOG INTEGRATED CIRCUIT

# $\mu$ PC8204TK

## VARIABLE GAIN AMPLIFIER FOR TRANSMITTER AGC

### DESCRIPTION

The  $\mu$ PC8204TK is a silicon monolithic integrated circuit designed as variable gain amplifier. The package is 6-pin lead-less minimold suitable for surface mount.

This IC is manufactured using our 30 GHz  $f_{max}$  UHS0 (Ultra High Speed Process) silicon bipolar process.

This IC is as same circuit current as conventional  $\mu$ PC8119T and  $\mu$ PC8120T, but operates at higher frequency and wider gain control range.

### FEATURES

- Gain control range : GCR = 40 dB TYP. @ f = 1.9 GHz  
: GCR = 40 dB TYP. @ f = 2.4 GHz
- Maximum power gain : G<sub>PMAX</sub> = 14.5 dB TYP. @ f = 1.9 GHz  
: G<sub>PMAX</sub> = 14.0 dB TYP. @ f = 2.4 GHz
- Operating frequency :  $f_{in}$  = 0.8 to 2.5 GHz
- Supply voltage :  $V_{CC}$  = 2.7 to 3.3 V
- High-density surface mounting : 6-pin lead-less minimold package

### APPLICATION

- 0.8 to 2.5 GHz transmitter/receiver system (PHS, WLAN and so on)

### ★ ORDERING INFORMATION

| Part Number       | Order Number        | Package   | Marking | Supplying Form   |
|-------------------|---------------------|---|---------|--|
| $\mu$ PC8204TK-E2 | $\mu$ PC8204TK-E2-A | 6-pin lead-less minimold (1511 PKG) (Pb-Free) <sup>Note</sup> | 6E      | <ul style="list-style-type: none"><li>• Embossed tape 8 mm wide</li><li>• Pin 1, 6 face the perforation side of the tape</li><li>• Qty 5 kpcs/reel</li></ul> |

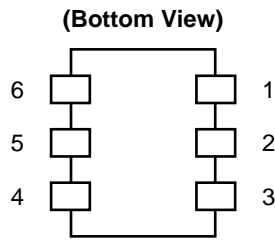
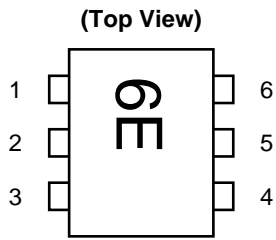
**Note** With regards to terminal solder (the solder contains lead) plated products (conventionally plated), contact your nearby sales office.

**Remark** To order evaluation samples, contact your nearby sales office.  
Part number for sample order:  $\mu$ PC8204TK

**Caution** Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

**PIN CONNECTIONS**



| Pin No. | Pin Name         |
|---------|------------------|
| 1       | INPUT            |
| 2       | GND              |
| 3       | GND              |
| 4       | OUTPUT           |
| 5       | V <sub>CC</sub>  |
| 6       | V <sub>AGC</sub> |

**VARIABLE GAIN AMPLIFIER PRODUCT LINE-UP**

| Parameter<br>Part No. | I <sub>CC</sub><br>(mA) | 0.95 GHz output port<br>matching frequency |                         |            | 1.44 GHz output port<br>matching frequency |                         |            | 1.9 GHz output port<br>matching frequency |                         |            | 2.4 GHz output port<br>matching frequency |                         |            |
|-----------------------|-------------------------|--|-------------------------|------------|--|-------------------------|------------|---|-------------------------|------------|---|-------------------------|------------|
|                       |                         | G <sub>PMAX</sub><br>(dB)                  | G <sub>CR</sub><br>(dB) | NF<br>(dB) | G <sub>PMAX</sub><br>(dB)                  | G <sub>CR</sub><br>(dB) | NF<br>(dB) | G <sub>PMAX</sub><br>(dB)                 | G <sub>CR</sub><br>(dB) | NF<br>(dB) | G <sub>PMAX</sub><br>(dB)                 | G <sub>CR</sub><br>(dB) | NF<br>(dB) |
| $\mu$ PC8204TK        | 11.5                    | -  | -                       | -          | -  | -                       | -          | 14.5                                      | 40                      | 7.5        | 14.0                                      | 40                      | 7.5        |
| $\mu$ PC8119T         | 11.0                    | 12.5                                       | 50                      | 8.5        | 13.0                                       | 45                      | 7.5        | (12.5)                                    | (22)                    | (7.2)      | -   | -                       | -          |
| $\mu$ PC8120T         | 11.0                    | 13.0                                       | 50                      | 9.0        | 13.5                                       | 45                      | 7.5        | (13.0)                                    | (22)                    | (7.3)      | -   | -                       | -          |

- Remarks 1.** Typical performance. Please refer to **ELECTRICAL CHARACTERISTICS** in detail. ( ): reference.  
**2.** To know the associated product, please refer to each latest data sheet.

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1. PIN EXPLANATION

| Pin No. | Pin Name  | Applied Voltage (V)                                   | Pin Voltage (V)<br><small>Note</small> | Function and Applications   | Internal Equivalent Circuit |
|---------|-----------|---|--|---|-----------------------------|
| 1       | INPUT     | –   | 1.2                                    | RF input pin.<br>This pin should be coupled with capacitor (example 100 pF) for DC cut. Input return loss can be improved with external impedance matching circuit.   |                             |
| 2<br>3  | GND       | 0   | –                                      | Ground pin.<br>This pin should be connected to system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible. Ground pins must be connected together with wide ground pattern to decrease impedance difference. |                             |
| 4       | OUTPUT    | Voltage as same as $V_{CC}$ through external inductor | –                                      | RF output pin.<br>This pin is designed as open collector of high impedance. This pin must be externally equipped with matching circuits.  |                             |
| 5       | $V_{CC}$  | 2.7 to 3.3  | –                                      | Supply voltage pin.<br>This pin must be equipped with bypass capacitor (example 1 000 pF) to minimize its RF impedance.   | —                           |
| 6       | $V_{AGC}$ | 0 to 3.3  | –                                      | Gain control pin.   |                             |

**Note** Pin voltage is measured at  $V_{CC} = 3.0 V$

**2. ABSOLUTE MAXIMUM RATINGS**

| Parameter                     | Symbol           | Test Conditions                    | Ratings     | Unit |
|-------------------------------|------------------|------------------------------------|-------------|------|
| Supply Voltage                | V <sub>CC</sub>  | T <sub>A</sub> = +25°C, Pin 4, 5   | 3.6         | V    |
| Total Circuit Current         | I <sub>CC</sub>  | T <sub>A</sub> = +25°C             | 30          | mA   |
| Gain Control Voltage          | V <sub>AGC</sub> | T <sub>A</sub> = +25°C             | 3.6         | V    |
| Power Dissipation             | P <sub>D</sub>   | T <sub>A</sub> = +85°C <b>Note</b> | 203         | mW   |
| Operating Ambient Temperature | T <sub>A</sub>   |                                    | -40 to +85  | °C   |
| Storage Temperature           | T <sub>stg</sub> |                                    | -55 to +150 | °C   |
| Input Power                   | P <sub>in</sub>  |                                    | +5          | dBm  |

**Note** Mounted on double-sided copper-clad 50 × 50 × 1.6 mm epoxy glass PWB

**3. RECOMMENDED OPERATING RANGE**

| Parameter                     | Symbol           | MIN. | TYP. | MAX. | Unit | Remarks  |
|-------------------------------|------------------|------|------|------|------|--|
| Supply Voltage                | V <sub>CC</sub>  | 2.7  | 3.0  | 3.3  | V    | Same voltage should be applied to pin 4 and pin 5. |
| Operating Ambient Temperature | T <sub>A</sub>   | -40  | +25  | +85  | °C   |  |
| Operating Frequency           | f <sub>in</sub>  | 0.8  | -    | 2.5  | GHz  | With external output-matching                      |
| Gain Control Voltage          | V <sub>AGC</sub> | 0    | -    | 3.3  | V    |  |

**4. ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = +25°C, V<sub>CC</sub> = V<sub>out</sub> = 3.0 V, Z<sub>s</sub> = Z<sub>L</sub> = 50 Ω, external matched output port, unless otherwise specified)**

| Parameter                          | Symbol              | Test Conditions  | MIN.         | TYP.         | MAX.         | Unit |
|------------------------------------|---------------------|--|--------------|--------------|--------------|------|
| Circuit Current                    | I <sub>CC</sub>     | No signal  | 8.5          | 11.5         | 15.0         | mA   |
| Maximum Power Gain                 | G <sub>PMAX</sub>   | f = 1.9 GHz, P <sub>in</sub> = -20 dBm<br>f = 2.4 GHz, P <sub>in</sub> = -20 dBm | 11.5<br>11.0 | 14.5<br>14.0 | 17.5<br>17.0 | dB   |
| Gain Control Range <sup>Note</sup> | GCR                 | f = 1.9 GHz, P <sub>in</sub> = -20 dBm<br>f = 2.4 GHz, P <sub>in</sub> = -20 dBm | 35<br>35     | 40<br>40     | -<br>-       | dB   |
| Gain 1 dB Compression Output Power | P <sub>O(1dB)</sub> | f = 1.9 GHz, G <sub>PMAX</sub><br>f = 2.4 GHz, G <sub>PMAX</sub>                 | +2.0<br>+2.0 | +5.0<br>+5.0 | -<br>-       | dBm  |
| Input Return Loss                  | RL <sub>in</sub>    | f = 1.9 GHz, G <sub>PMAX</sub><br>f = 2.4 GHz, G <sub>PMAX</sub>                 | 8<br>9       | 11<br>13     | -<br>-       | dB   |
| Isolation                          | ISL                 | f = 1.9 GHz, G <sub>PMAX</sub><br>f = 2.4 GHz, G <sub>PMAX</sub>                 | 25<br>25     | 30<br>30     | -<br>-       | dB   |
| Noise Figure                       | NF                  | f = 1.9 GHz, G <sub>PMAX</sub><br>f = 2.4 GHz, G <sub>PMAX</sub>                 | -<br>-       | 7.5<br>7.5   | 10.0<br>10.0 | dB   |

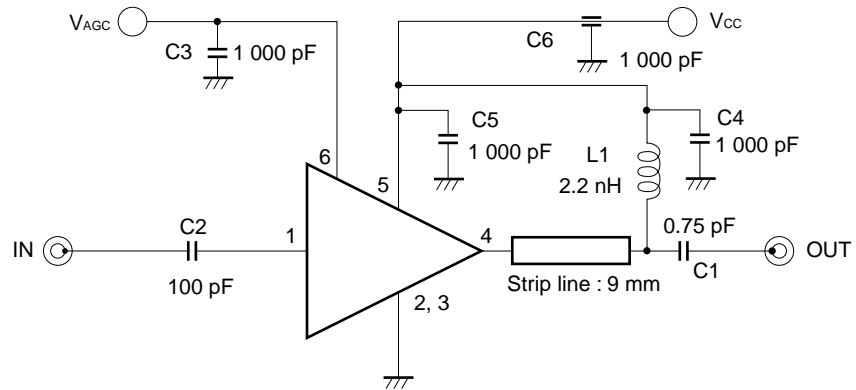
**Note** Gain control range GCR specification : GCR = G<sub>PMAX</sub> - G<sub>PMIN</sub> (dB)

Conditions      G<sub>PMAX</sub>@V<sub>AGC</sub> = V<sub>CC</sub>, G<sub>PMIN</sub>@V<sub>AGC</sub> = 0 V

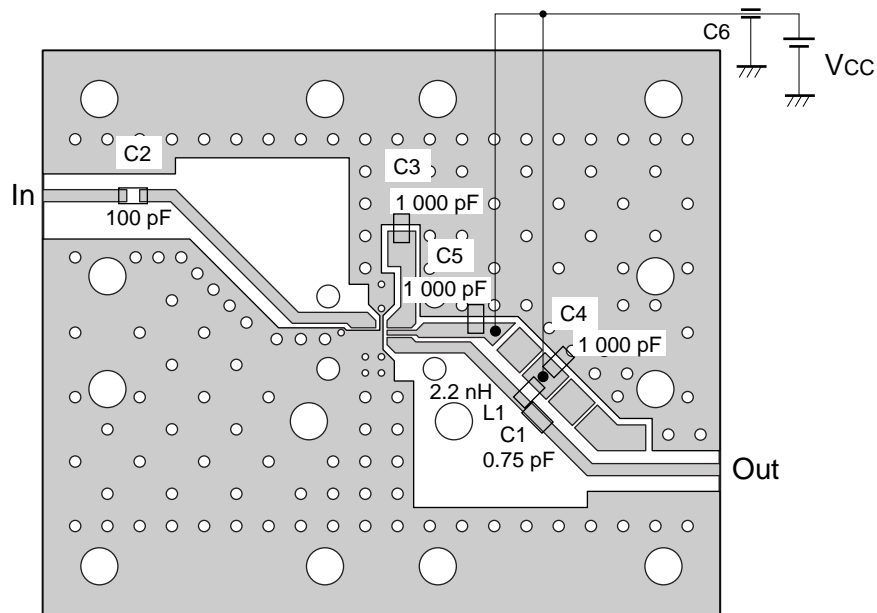
★ 5. TEST CIRCUITS

5.1 f = 1.9 GHz

5.1.1 Test circuit 1



5.1.2 Illustration of the test circuit 1 assembled on evaluation board

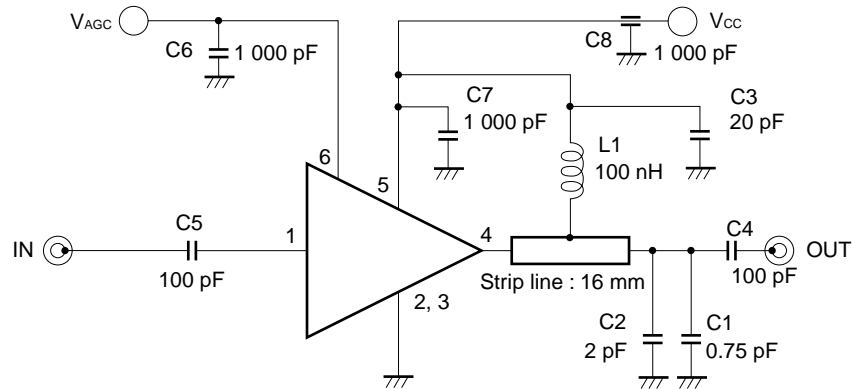


5.1.3 Component list

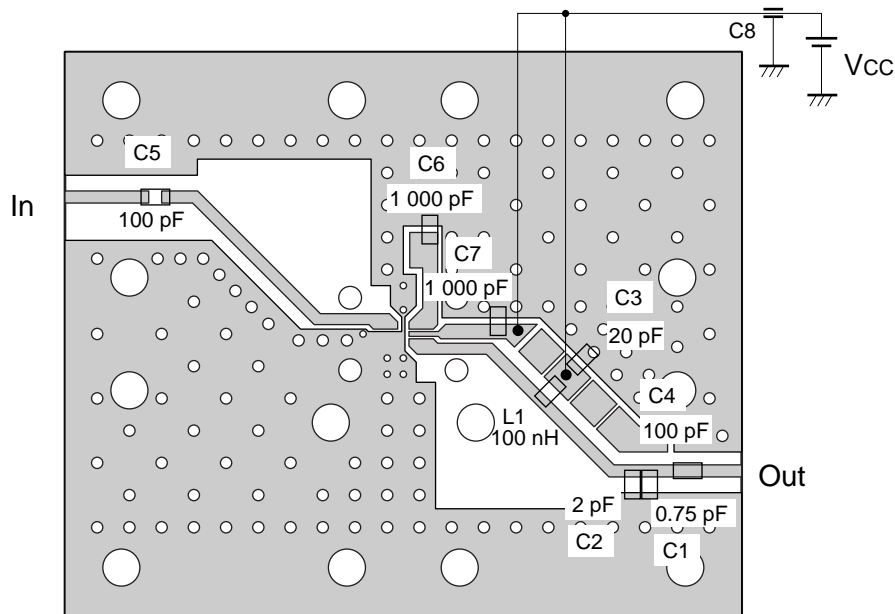
| Symbol | Form                   | Rating   | Part Number         | Maker  |
|--------|------------------------|----------|---------------------|--------|
| C1     | Chip Capacitor         | 0.75 pF  | GRM39               | Murata |
| C2     | Chip Capacitor         | 100 pF   | GRM39               | Murata |
| C3, C4 | Chip Capacitor         | 1 000 pF | GRM39               | Murata |
| C5     | Chip Capacitor         | 1 000 pF | GRM40               | Murata |
| C6     | Feed-through Capacitor | 1 000 pF | DFT301-801X7R102S50 | Murata |
| L1     | Chip Inductor          | 2.2 nH   | LL-2012             | TOKO   |

5.2 f = 2.4 GHz

5.2.1 Test circuit 2



5.2.2 Illustration of the test circuit 2 assembled on evaluation board

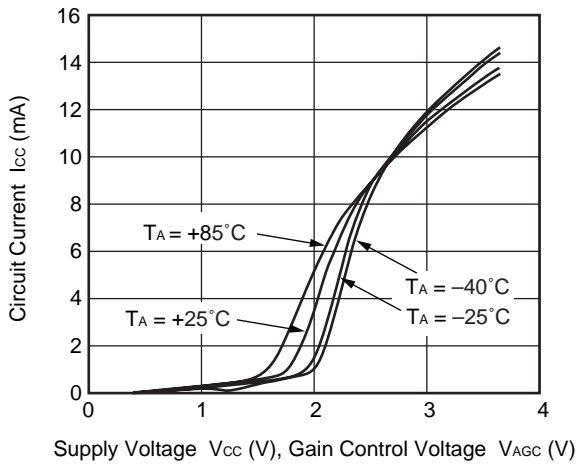


5.2.3 Component list

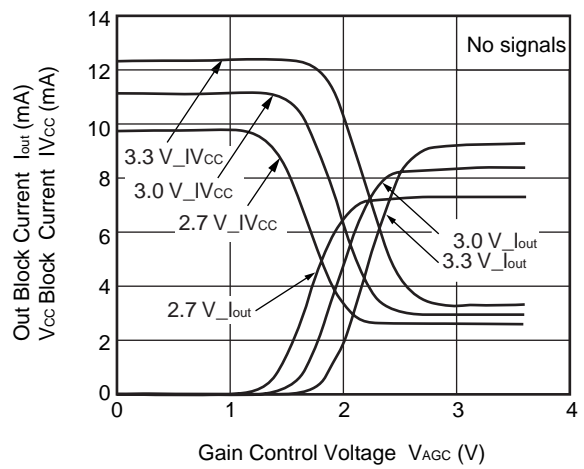
| Symbol | Form                   | Rating   | Part Number         | Maker  |
|--------|------------------------|----------|---------------------|--------|
| C1     | Chip Capacitor         | 0.75 pF  | GRM39               | Murata |
| C2     | Chip Capacitor         | 2 pF     | GRM39               | Murata |
| C3     | Chip Capacitor         | 20 pF    | GRM39               | Murata |
| C4, C5 | Chip Capacitor         | 100 pF   | GRM39               | Murata |
| C6     | Chip Capacitor         | 1 000 pF | GRM39               | Murata |
| C7     | Chip Capacitor         | 1 000 pF | GRM40               | Murata |
| C8     | Feed-through Capacitor | 1 000 pF | DFT301-801X7R102S50 | Murata |
| L1     | Chip Inductor          | 100 nH   | LL-1608             | TOKO   |

★ 6. TYPICAL CHARACTERISTICS ( $T_A = +25^\circ\text{C}$ , unless otherwise specified)

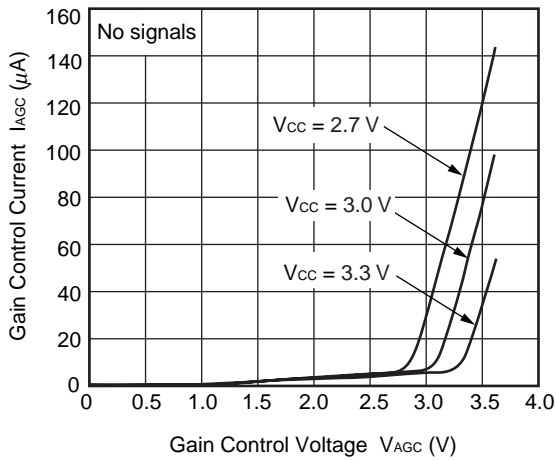
CIRCUIT CURRENT vs. SUPPLY VOLTAGE, GAIN CONTROL VOLTAGE



OUT BLOCK CURRENT AND  $V_{CC}$  BLOCK CURRENT vs. GAIN CONTROL VOLTAGE



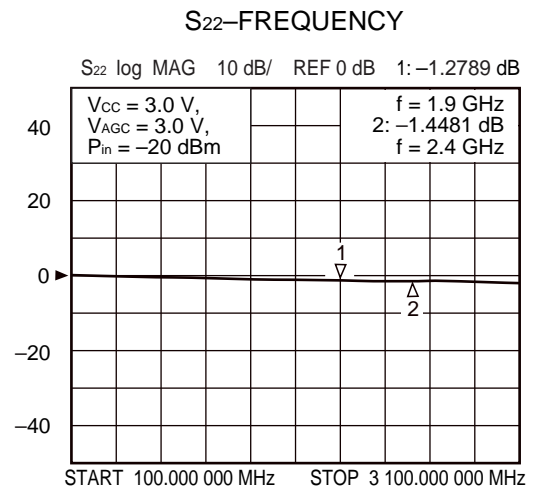
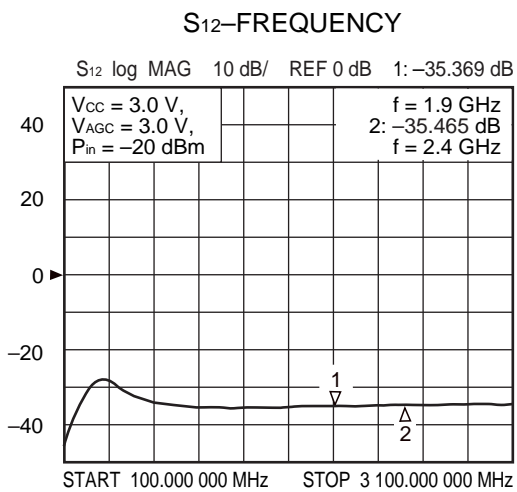
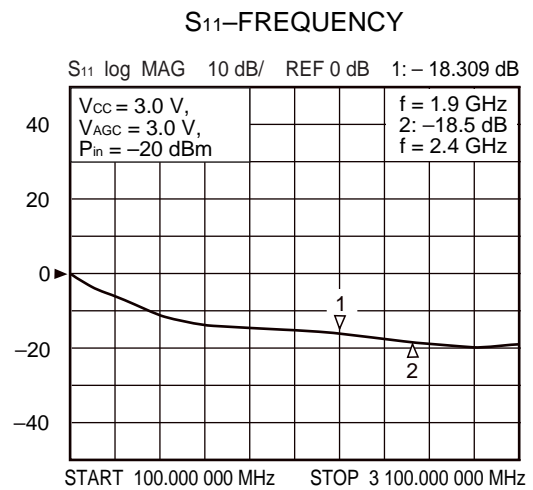
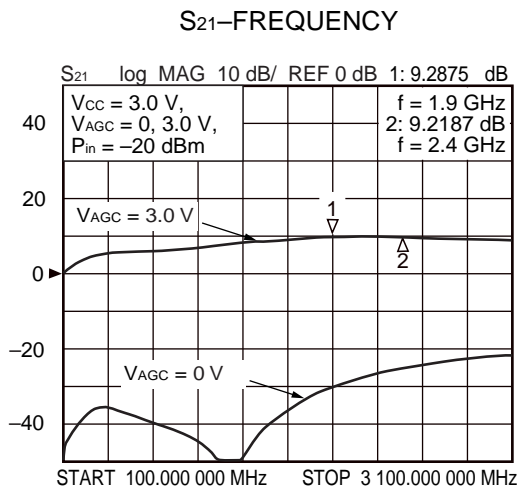
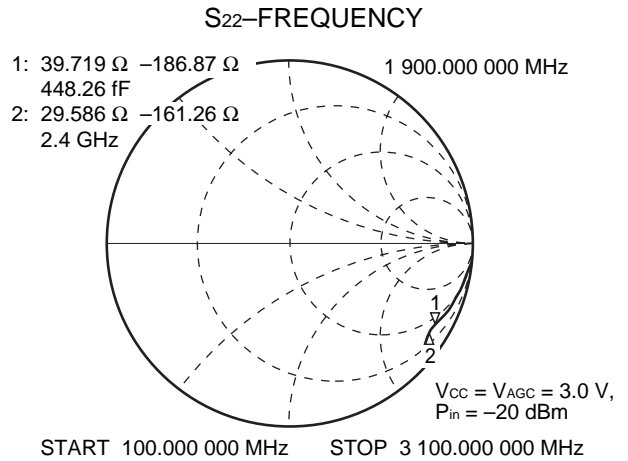
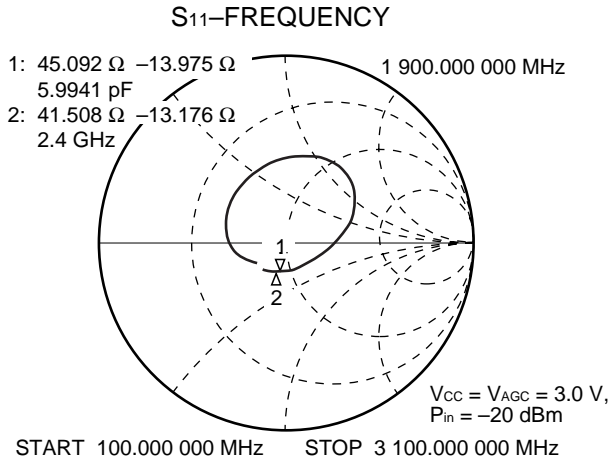
GAIN CONTROL CURRENT vs. GAIN CONTROL VOLTAGE



**Remark** The graphs indicate nominal characteristics.

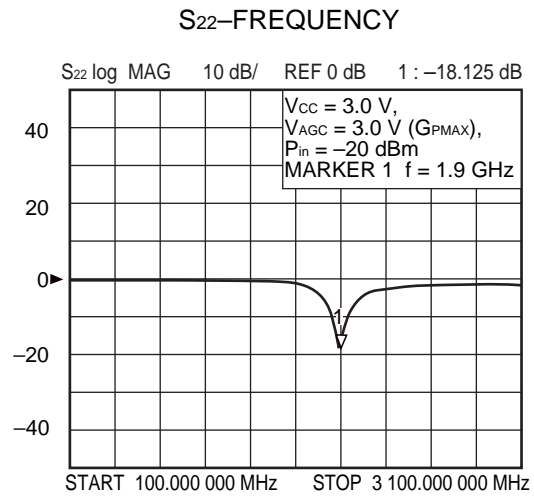
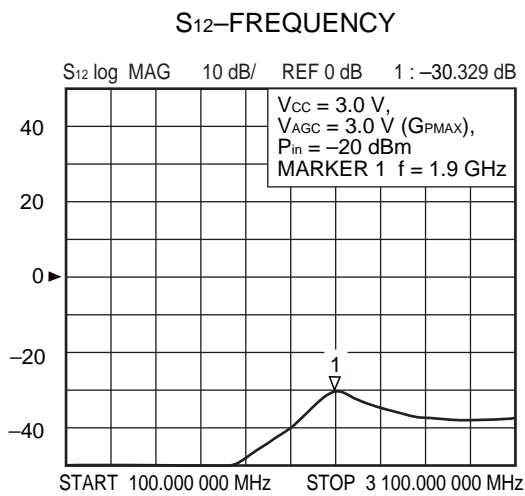
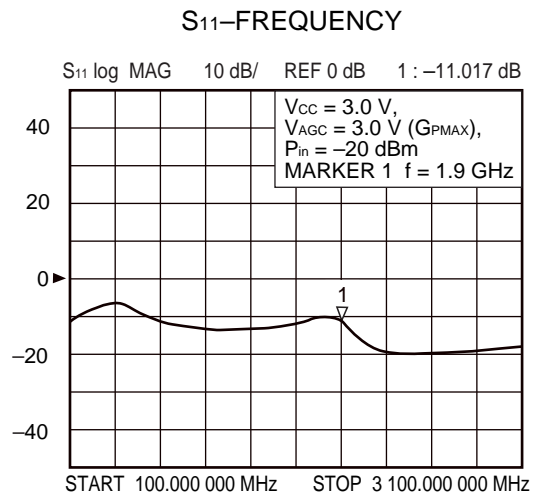
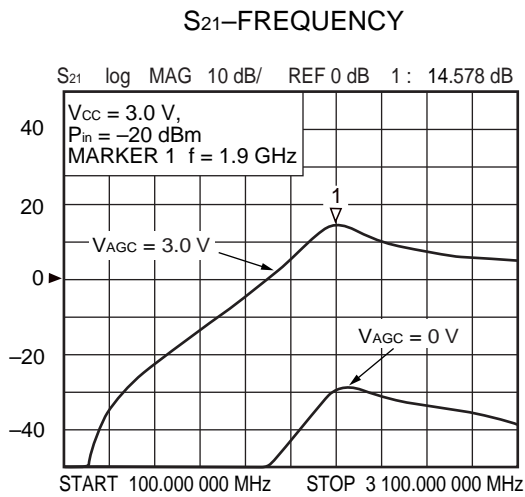
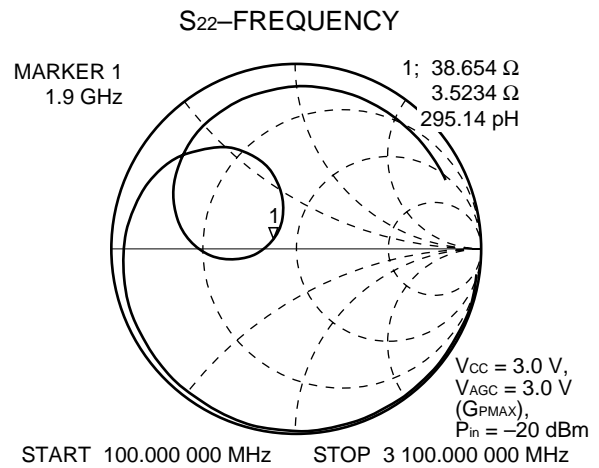
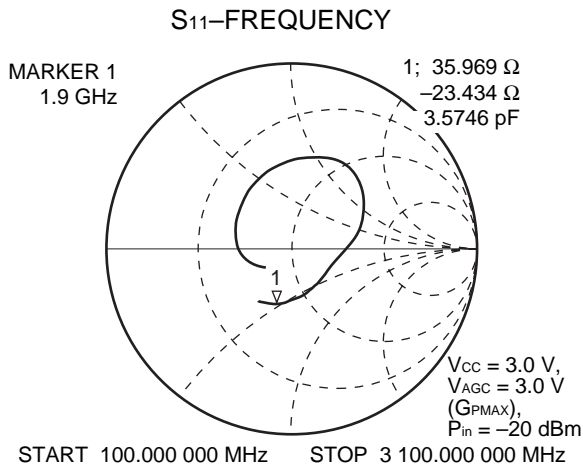


6.1 Inductor loading with external bias tee at output port



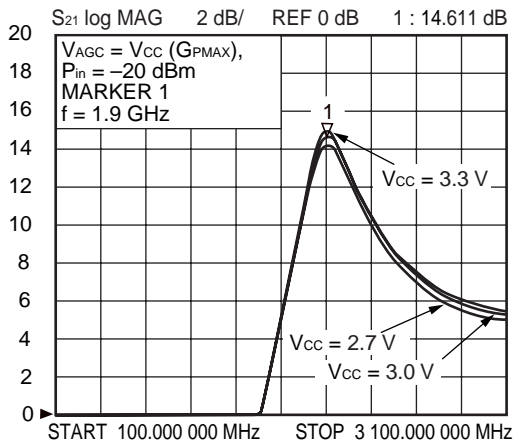
**Remark** The graphs indicate nominal characteristics.

6.2 Output port matching at f = 1.9 GHz

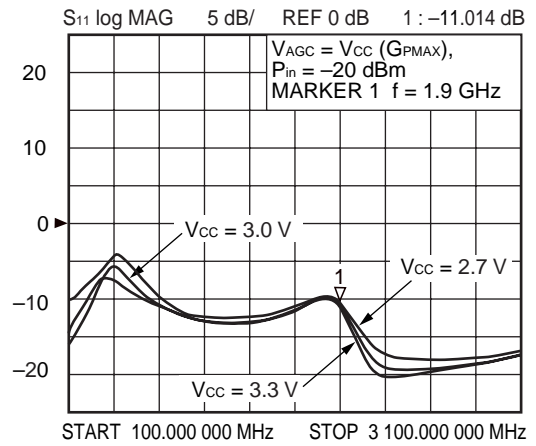


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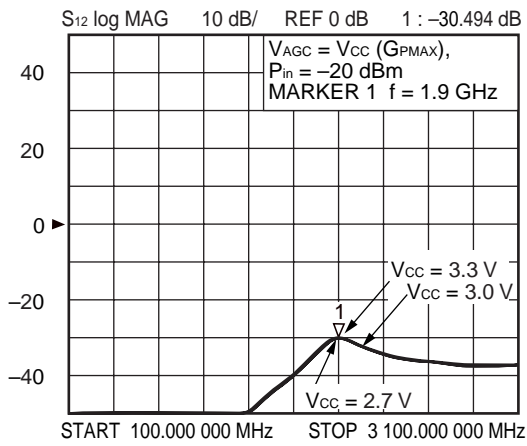
S21-FREQUENCY



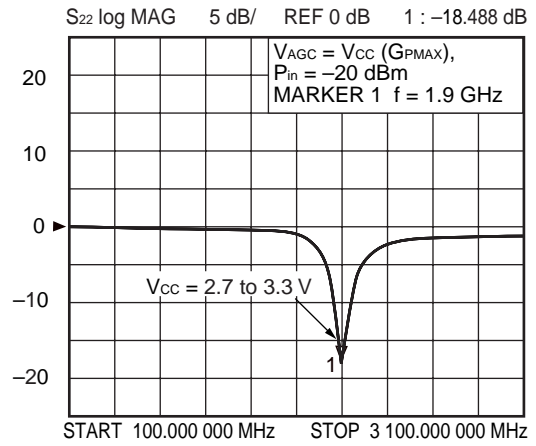
S11-FREQUENCY



S12-FREQUENCY

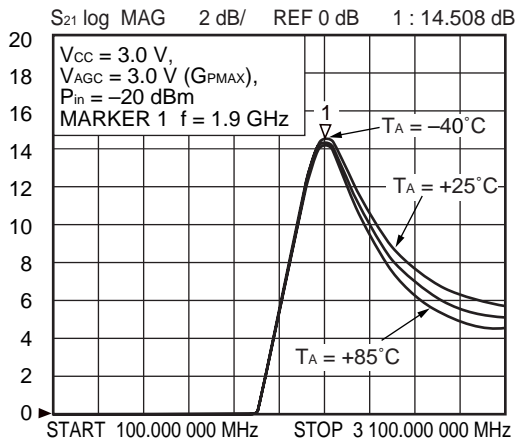


S22-FREQUENCY

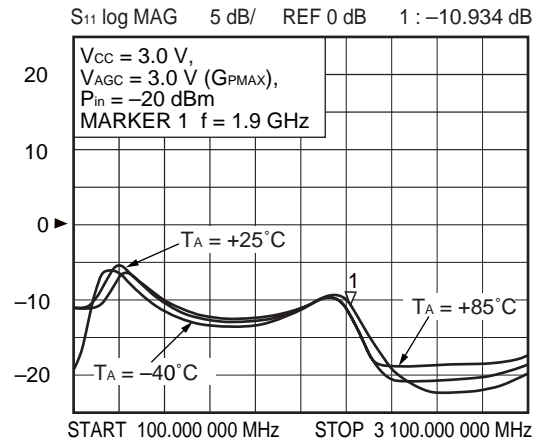


**Remark** The graphs indicate nominal characteristics.

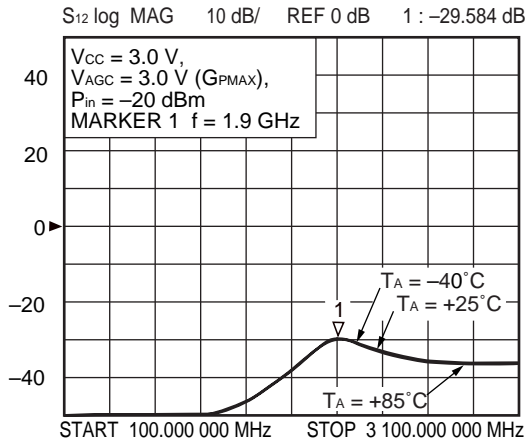
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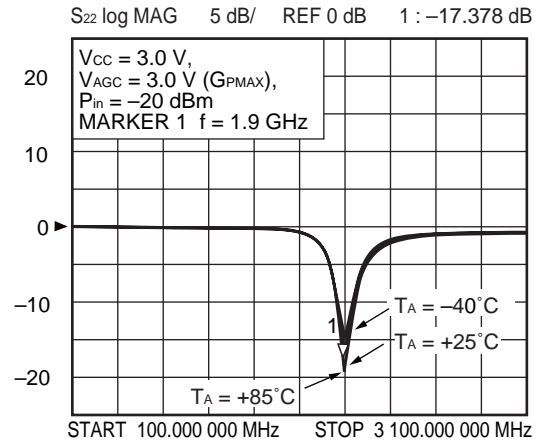
S<sub>11</sub>-FREQUENCY



S<sub>12</sub>-FREQUENCY

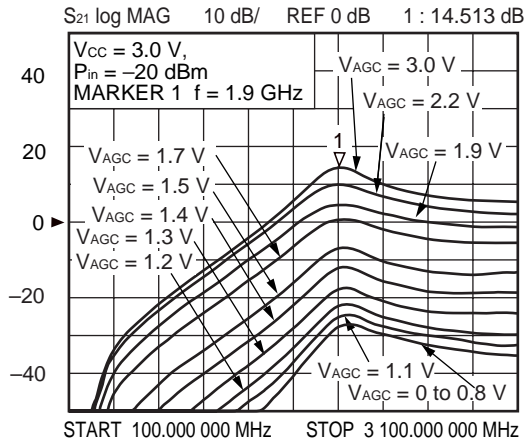


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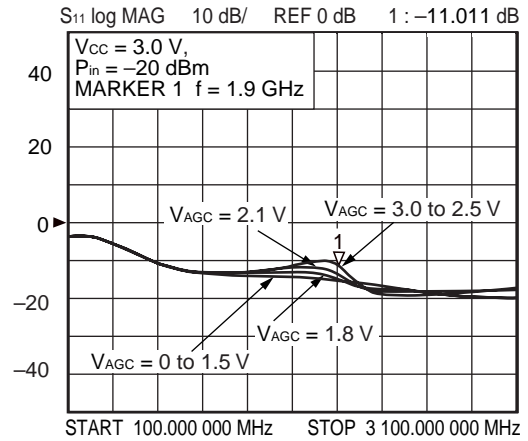


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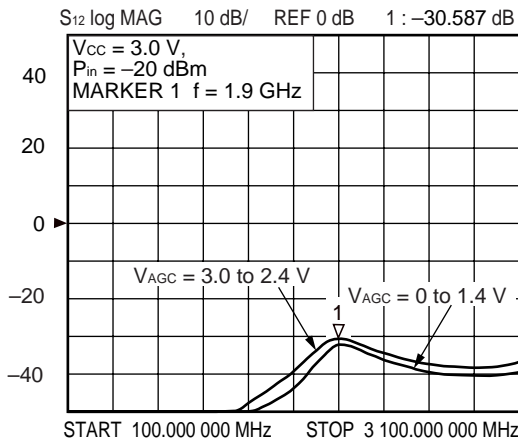
S21-FREQUENCY



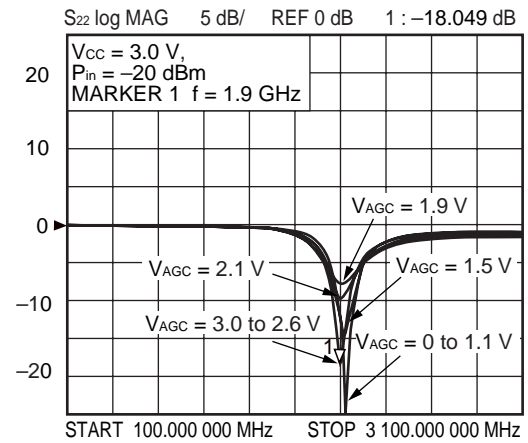
S11-FREQUENCY



S12-FREQUENCY

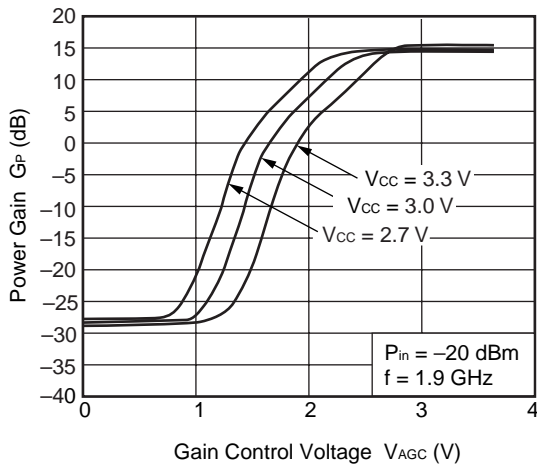


S22-FREQUENCY

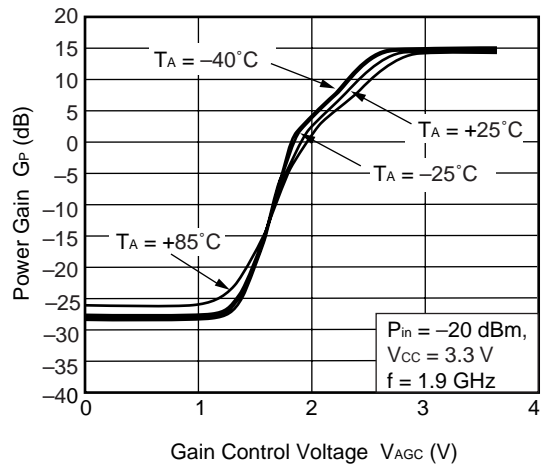


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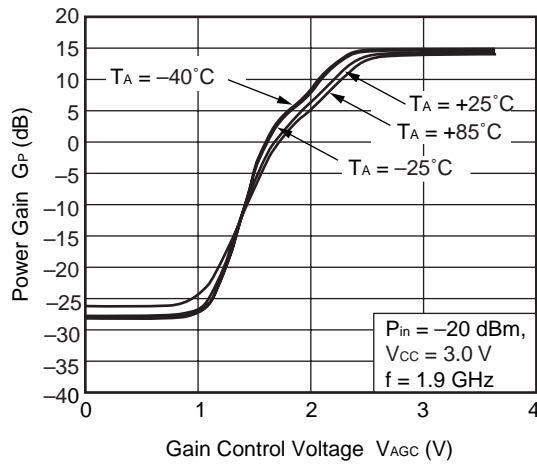
POWER GAIN vs. GAIN CONTROL VOLTAGE



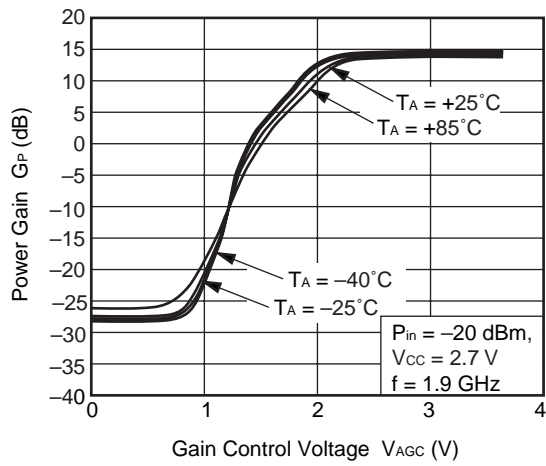
POWER GAIN vs. GAIN CONTROL VOLTAGE



POWER GAIN vs. GAIN CONTROL VOLTAGE

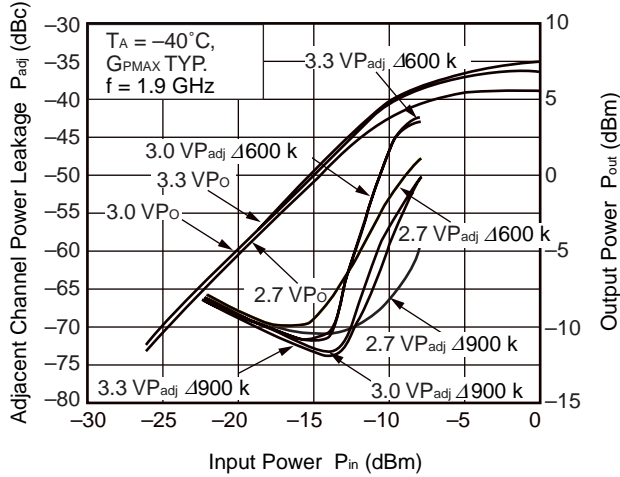


POWER GAIN vs. GAIN CONTROL VOLTAGE

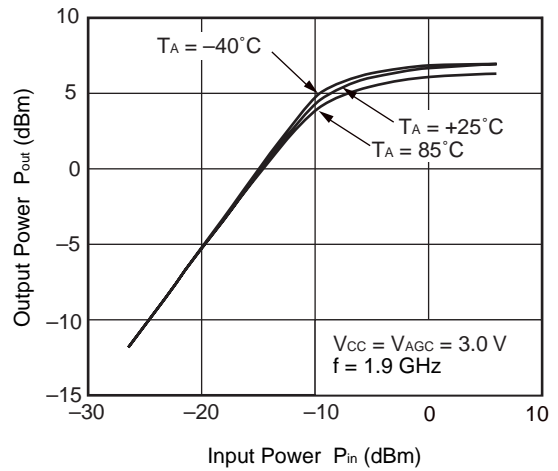


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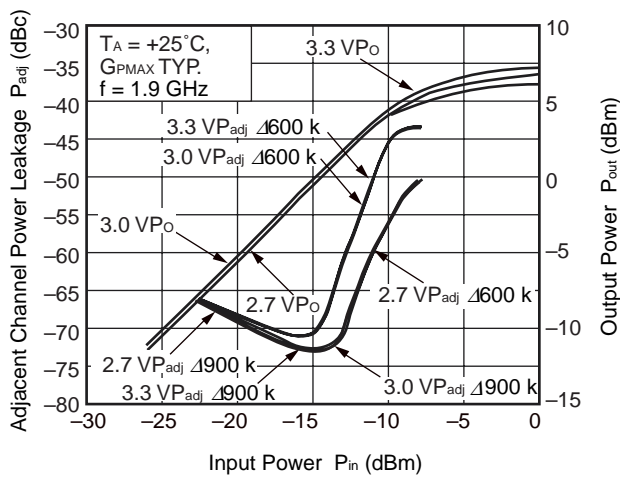
ADJACENT CHANNEL POWER LEAKAGE, OUTPUT POWER vs. INPUT POWER



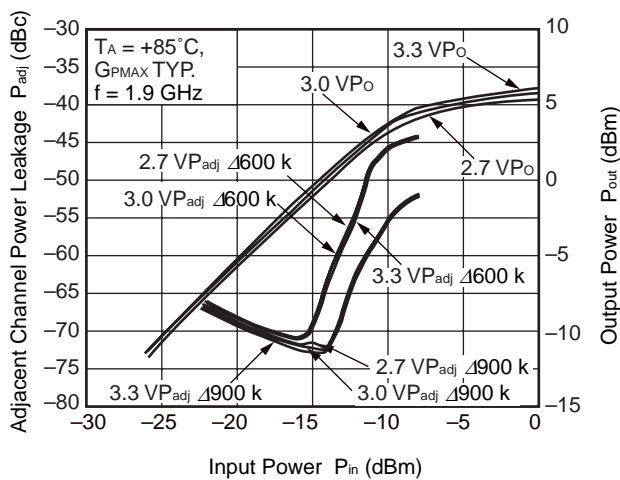
OUTPUT POWER vs. INPUT POWER



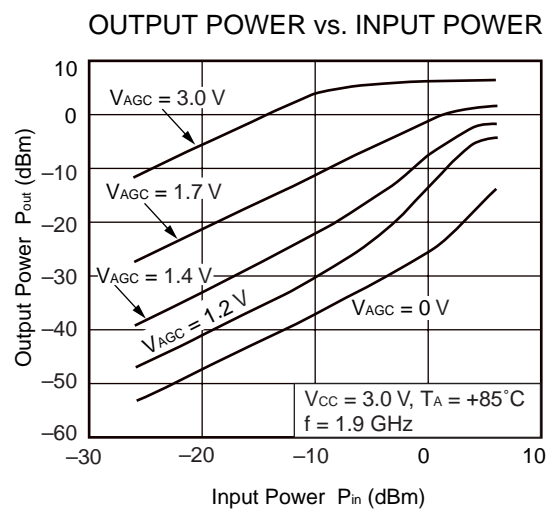
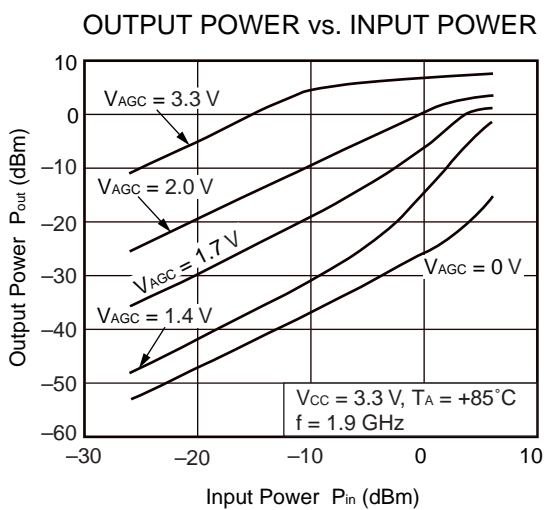
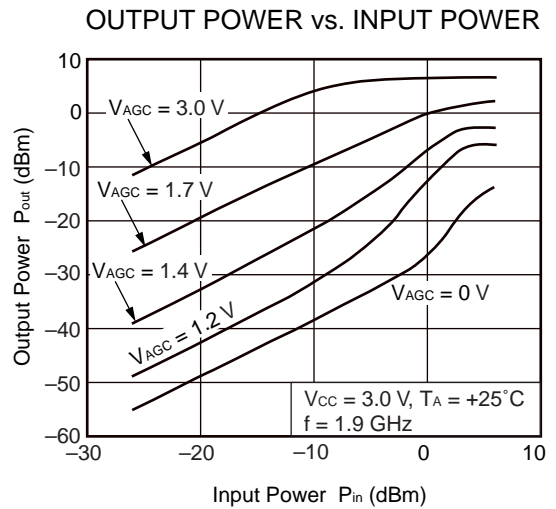
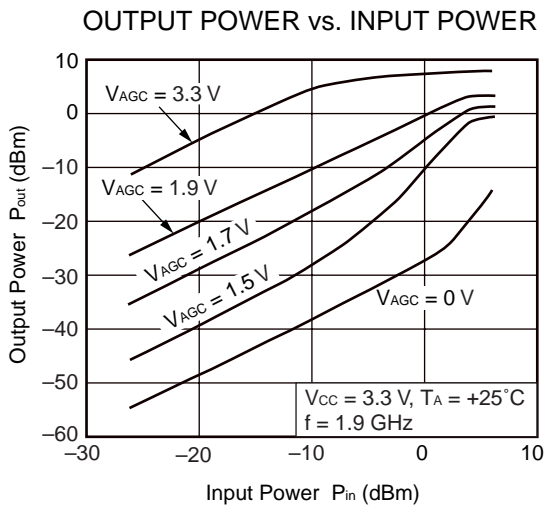
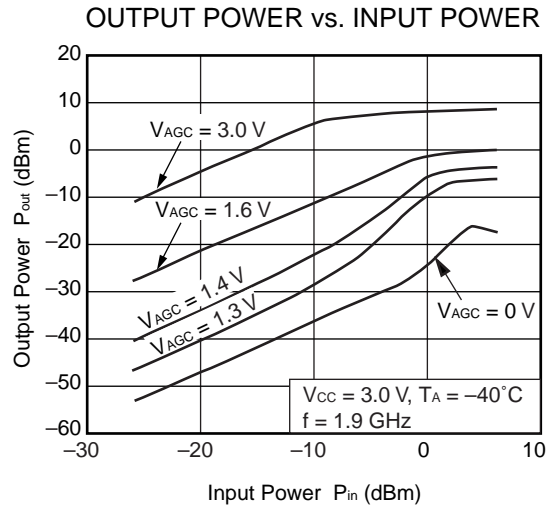
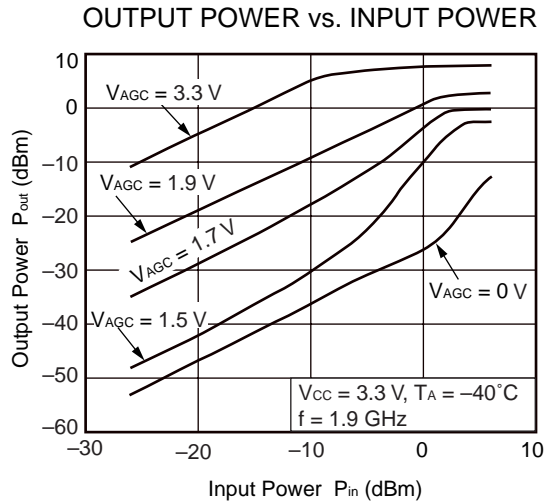
ADJACENT CHANNEL POWER LEAKAGE, OUTPUT POWER vs. INPUT POWER



ADJACENT CHANNEL POWER LEAKAGE, OUTPUT POWER vs. INPUT POWER



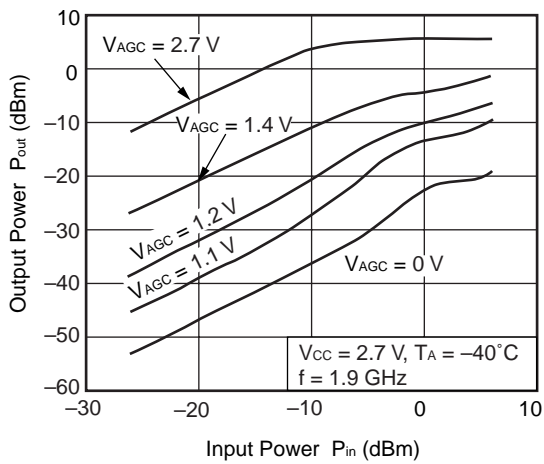
**Remark** The graphs indicate nominal characteristics.



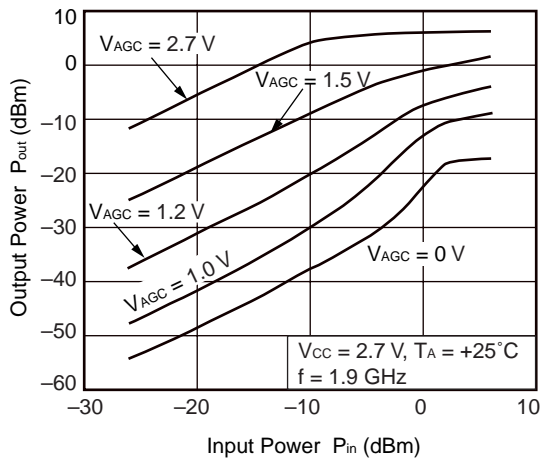
**Remark** The graphs indicate nominal characteristics.



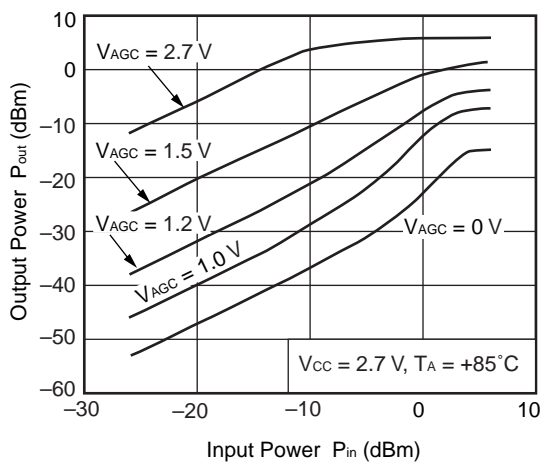
OUTPUT POWER vs. INPUT POWER



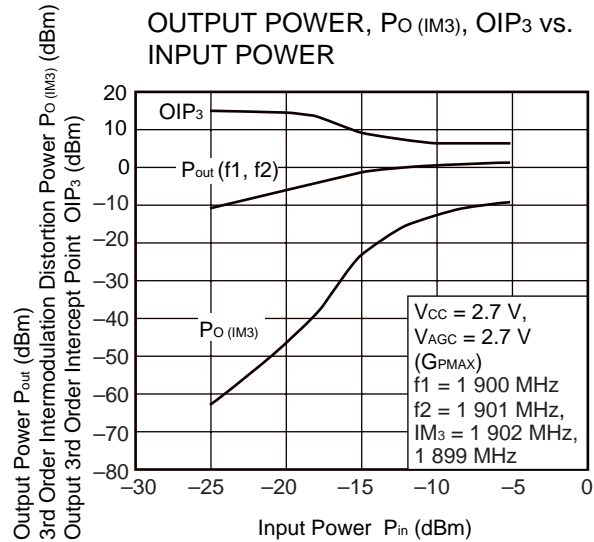
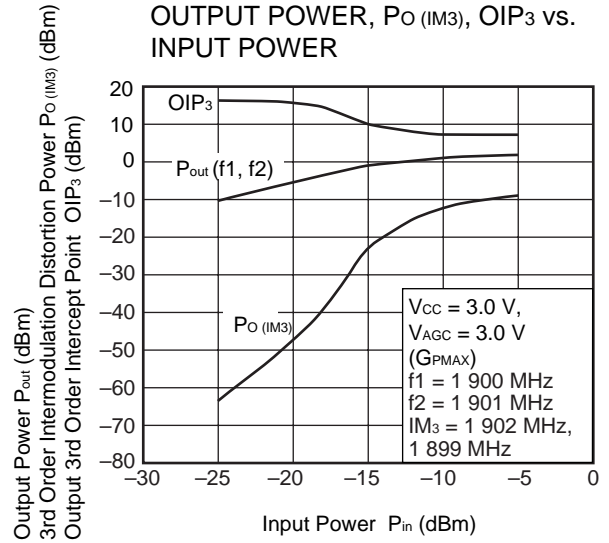
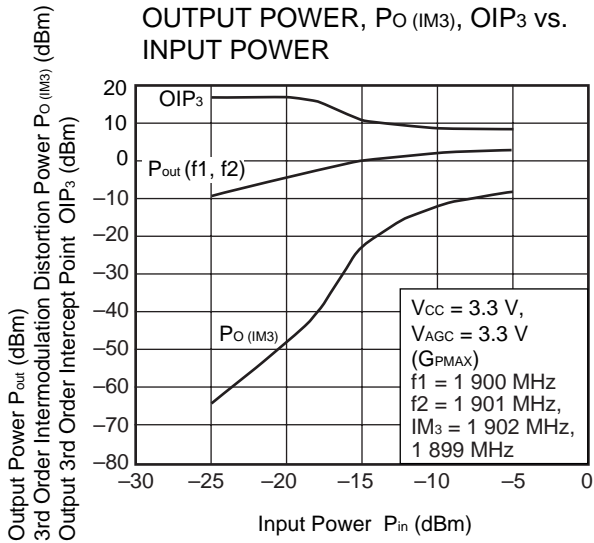
OUTPUT POWER vs. INPUT POWER



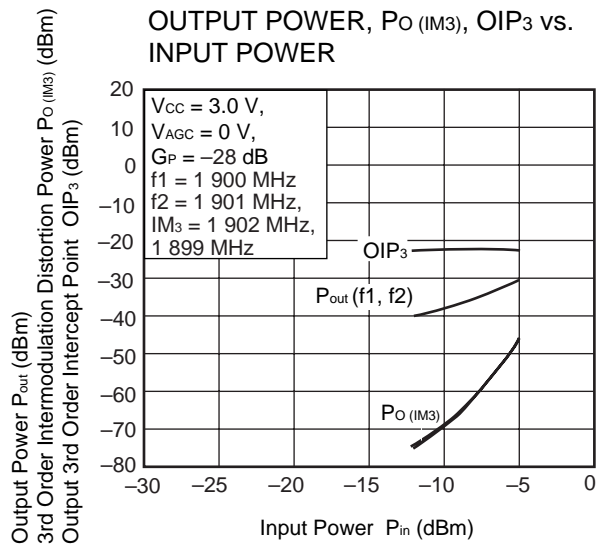
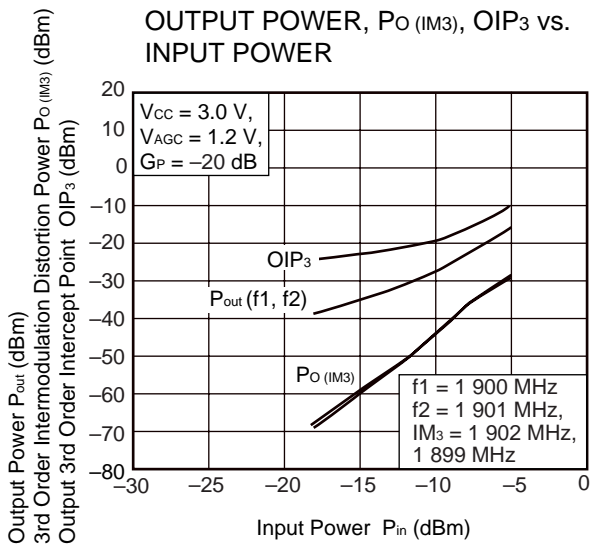
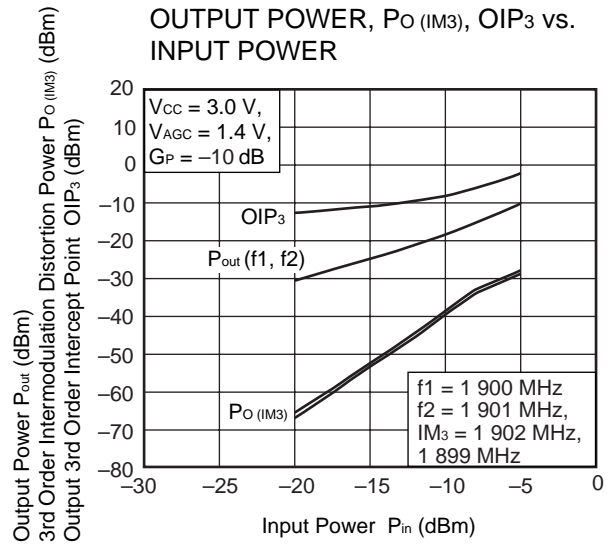
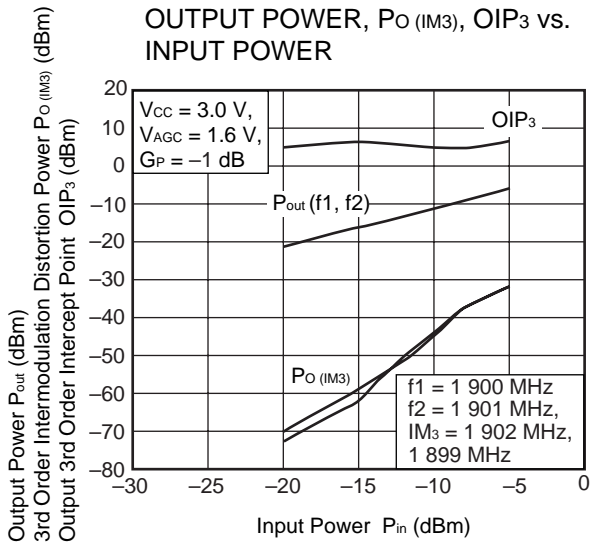
OUTPUT POWER vs. INPUT POWER



**Remark** The graphs indicate nominal characteristics.

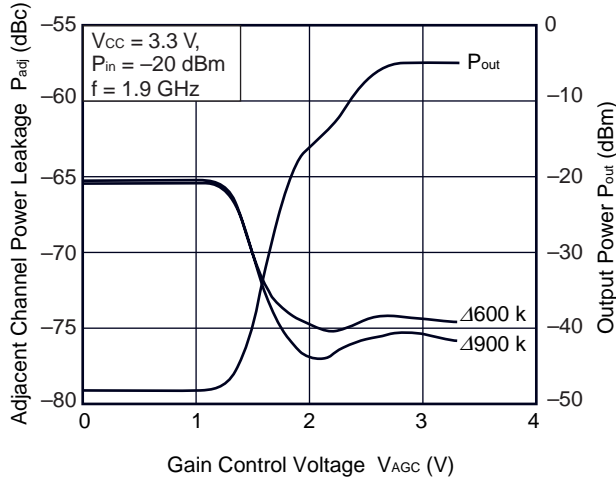


**Remark** The graphs indicate nominal characteristics.

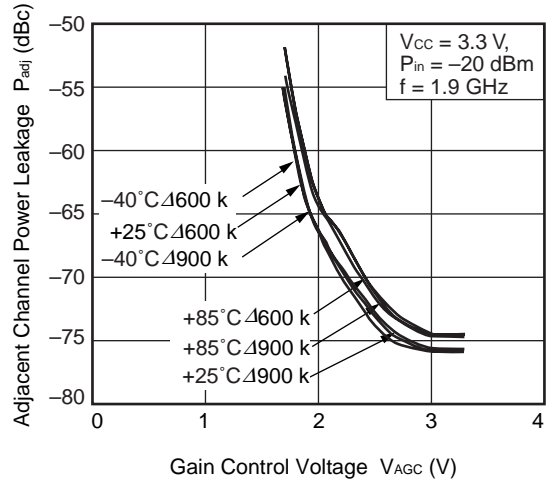


**Remark** The graphs indicate nominal characteristics.

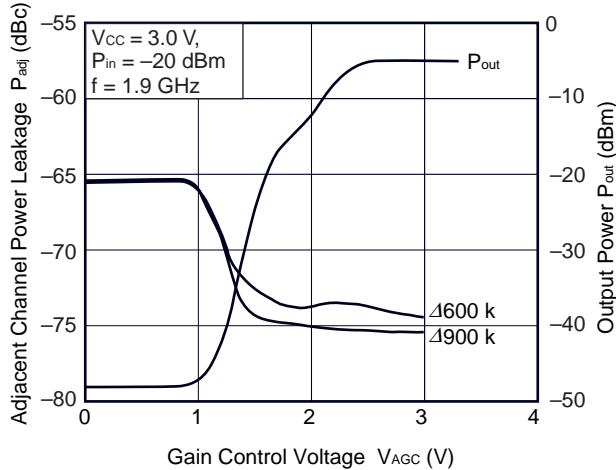
ADJACENT CHANNEL POWER LEAKAGE, OUTPUT POWER vs. GAIN CONTROL VOLTAGE



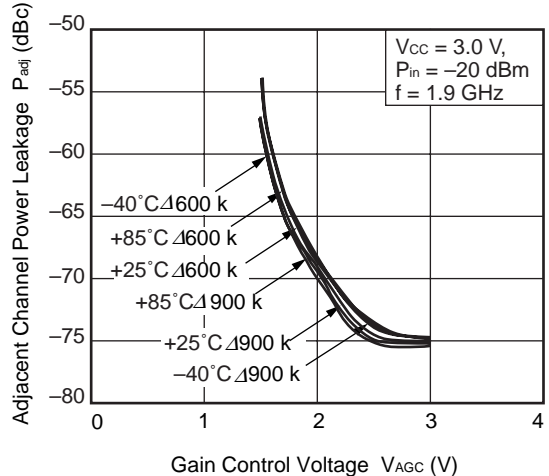
ADJACENT CHANNEL POWER LEAKAGE vs. GAIN CONTROL VOLTAGE



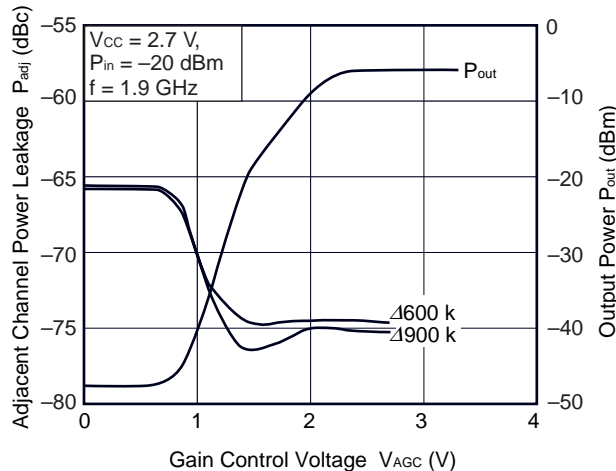
ADJACENT CHANNEL POWER LEAKAGE, OUTPUT POWER vs. GAIN CONTROL VOLTAGE



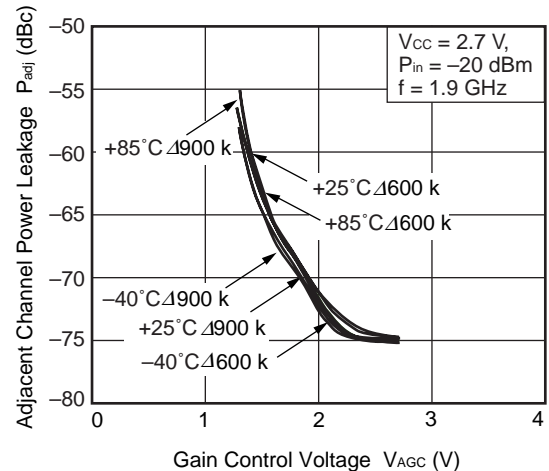
ADJACENT CHANNEL POWER LEAKAGE vs. GAIN CONTROL VOLTAGE



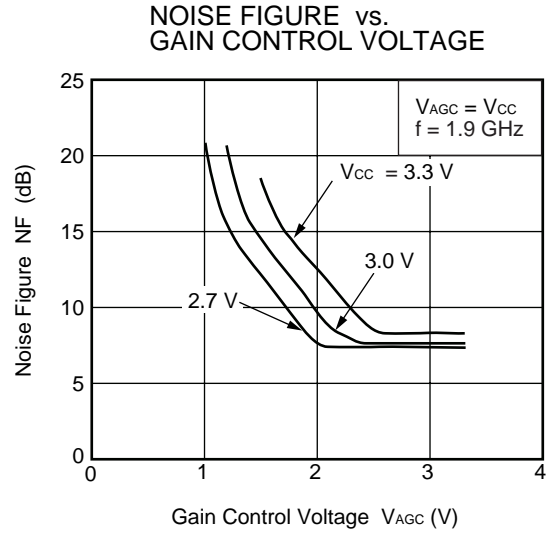
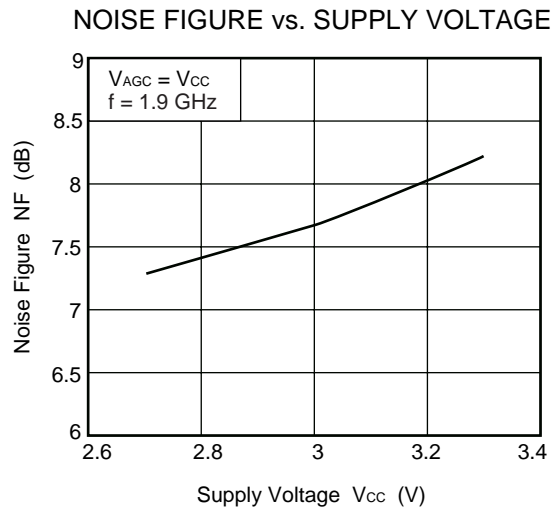
ADJACENT CHANNEL POWER LEAKAGE, OUTPUT POWER vs. GAIN CONTROL VOLTAGE



ADJACENT CHANNEL POWER LEAKAGE vs. GAIN CONTROL VOLTAGE

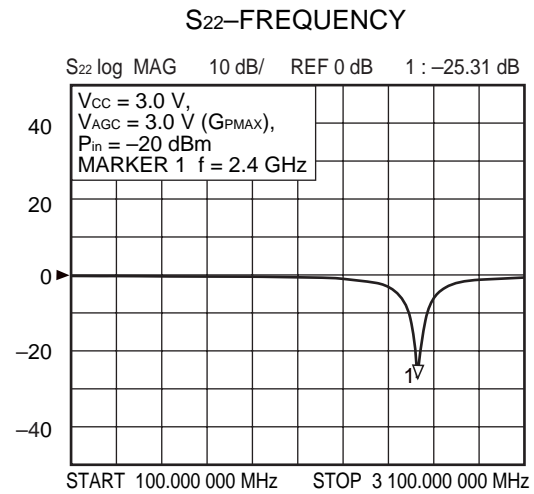
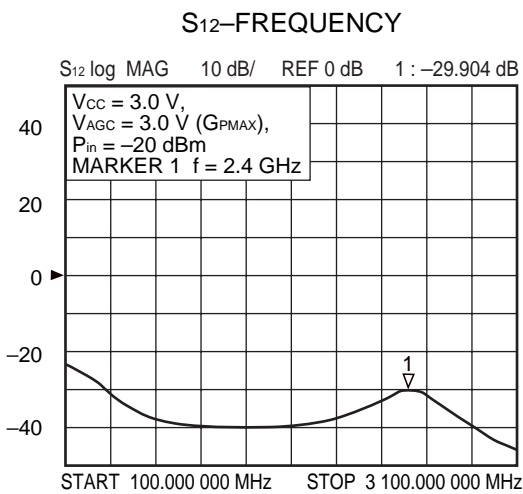
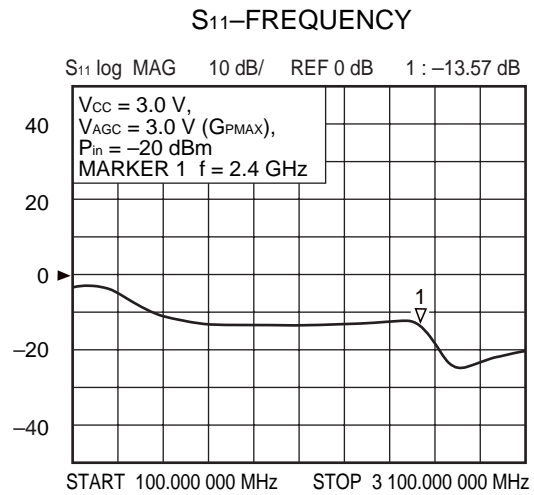
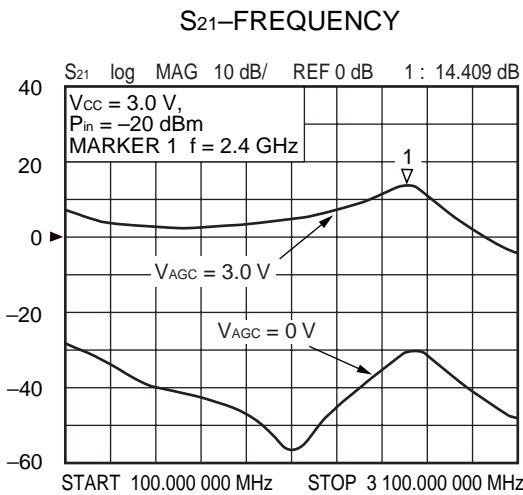
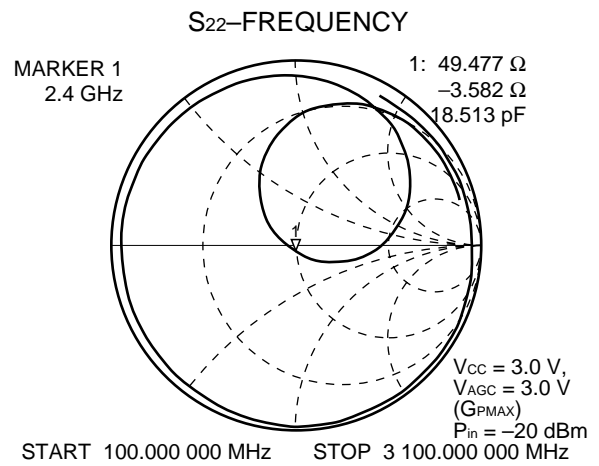
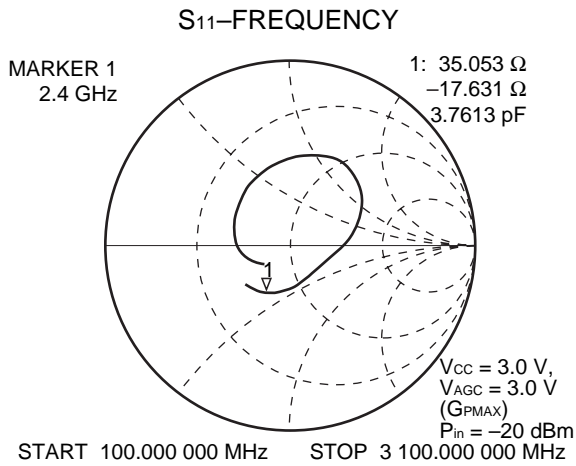


**Remark** The graphs indicate nominal characteristics.



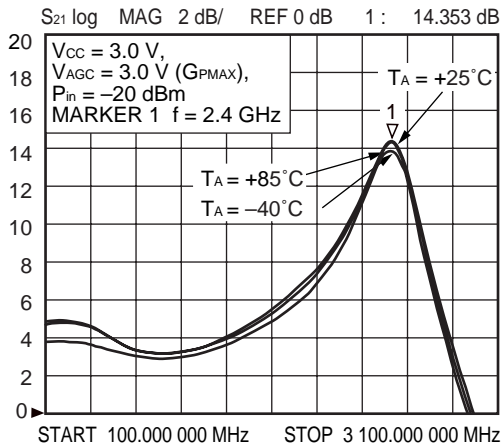
**Remark** The graphs indicate nominal characteristics.

6.3 Output port matching at f = 2.4 GHz

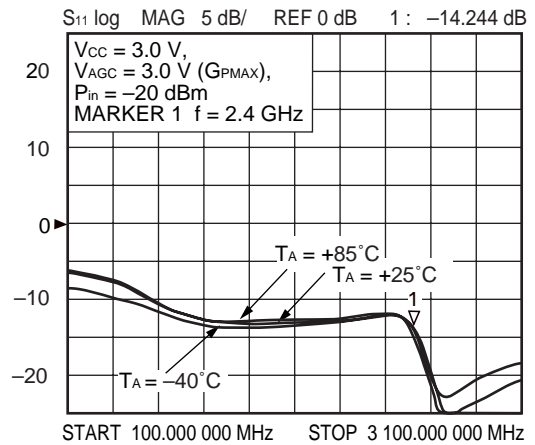


**Remark** The graphs indicate nominal characteristics.

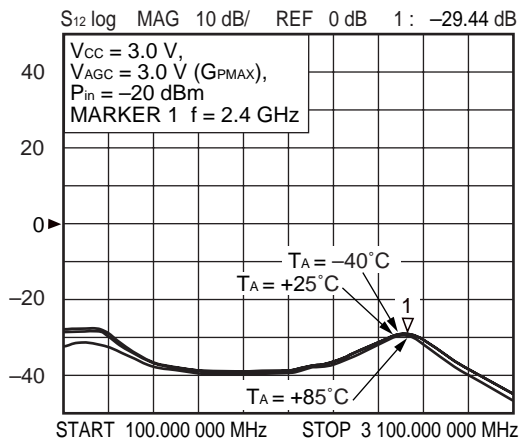
S<sub>21</sub>-FREQUENCY



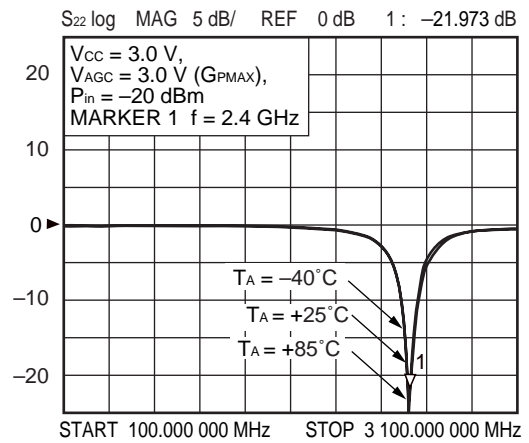
S<sub>11</sub>-FREQUENCY



S<sub>12</sub>-FREQUENCY

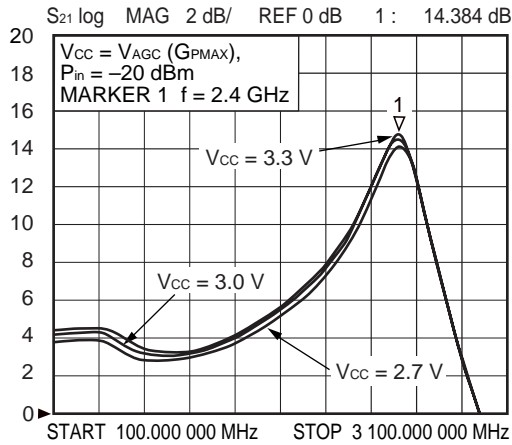


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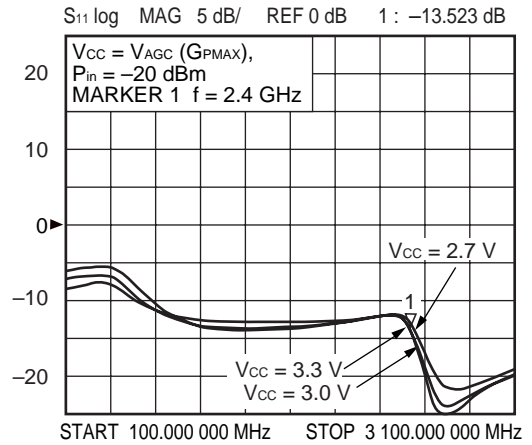


**Remark** The graphs indicate nominal characteristics.

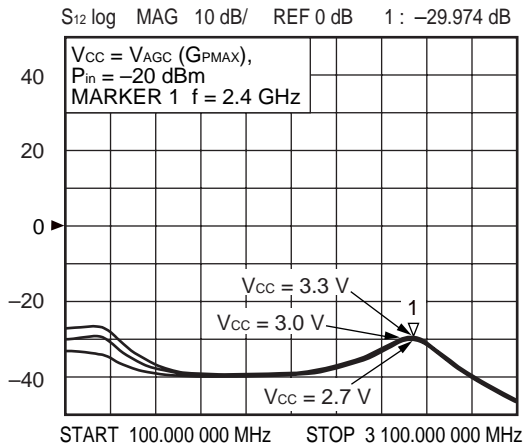
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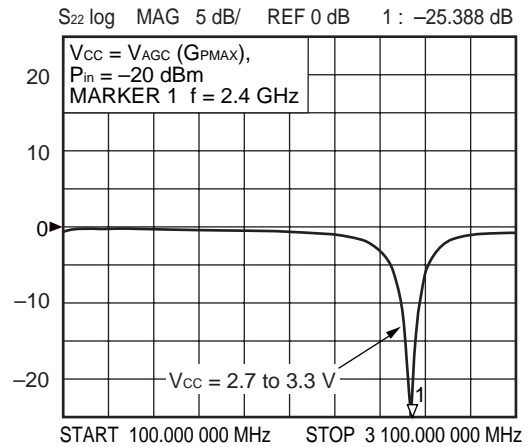
S<sub>11</sub>-FREQUENCY



S<sub>12</sub>-FREQUENCY



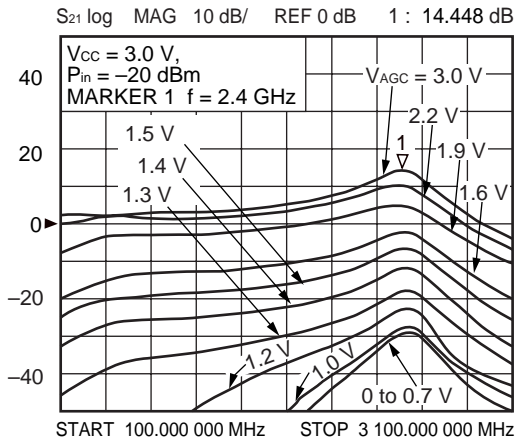
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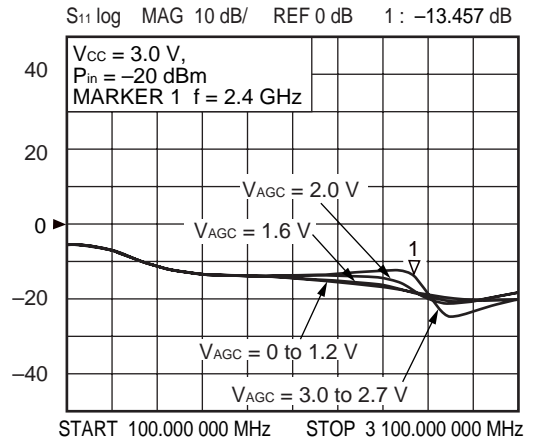
**Remark** The graphs indicate nominal characteristics.



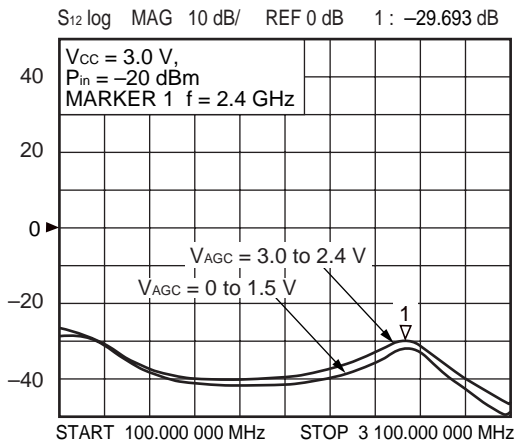
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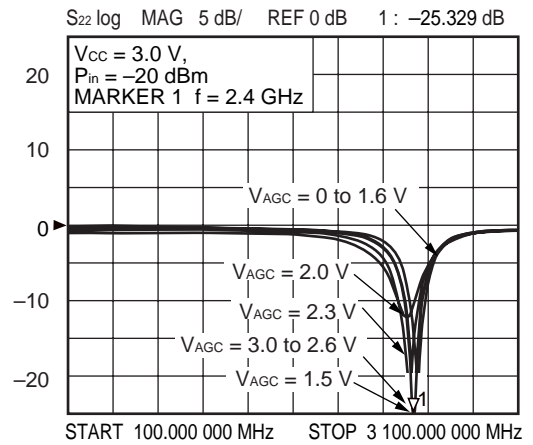
S11-FREQUENCY



S12-FREQUENCY

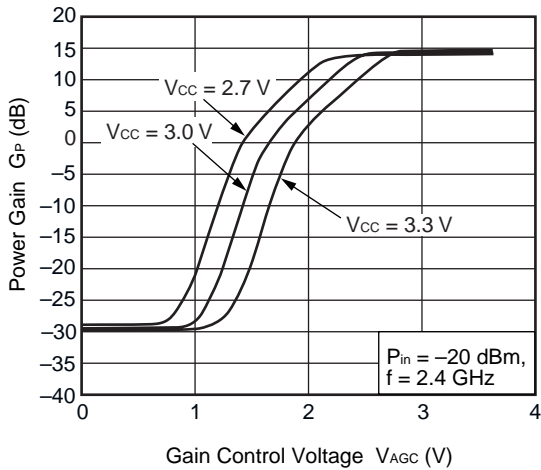


S22-FREQUENCY

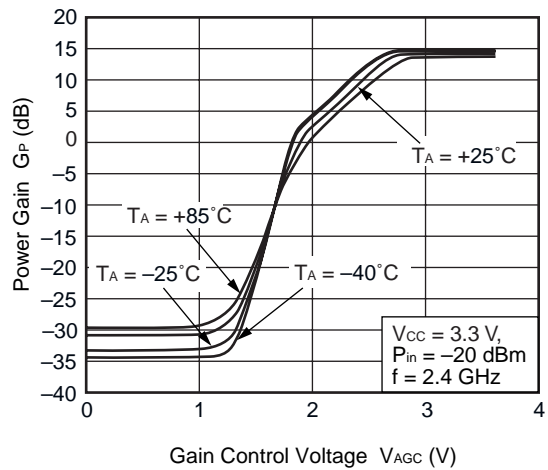


**Remark** The graphs indicate nominal characteristics.

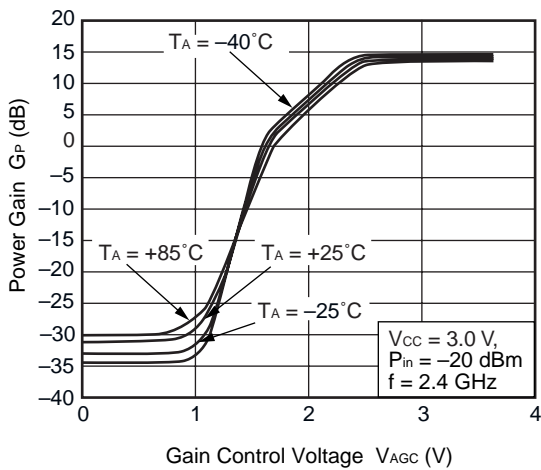
POWER GAIN vs. GAIN CONTROL VOLTAGE



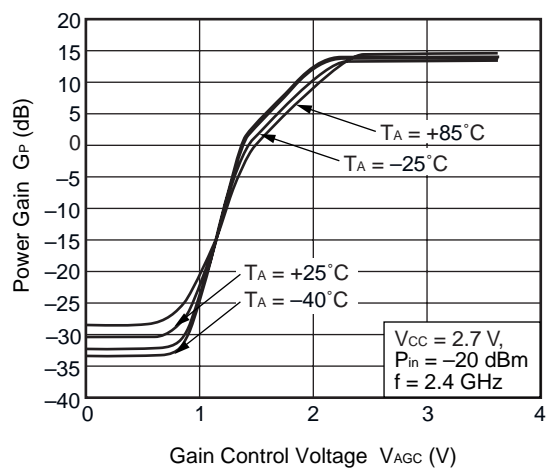
POWER GAIN vs. GAIN CONTROL VOLTAGE



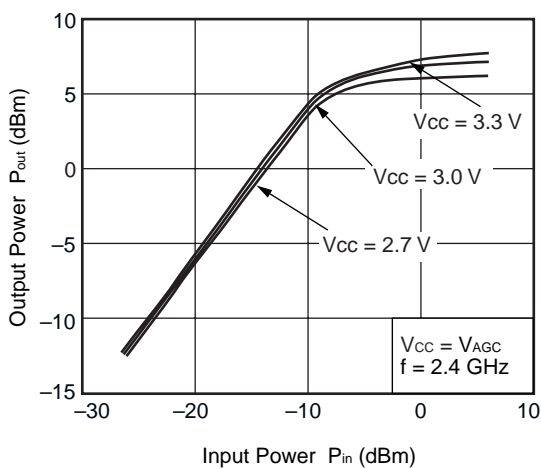
POWER GAIN vs. GAIN CONTROL VOLTAGE



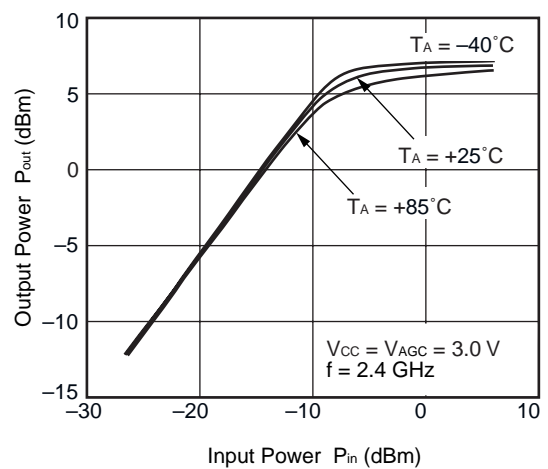
POWER GAIN vs. GAIN CONTROL VOLTAGE



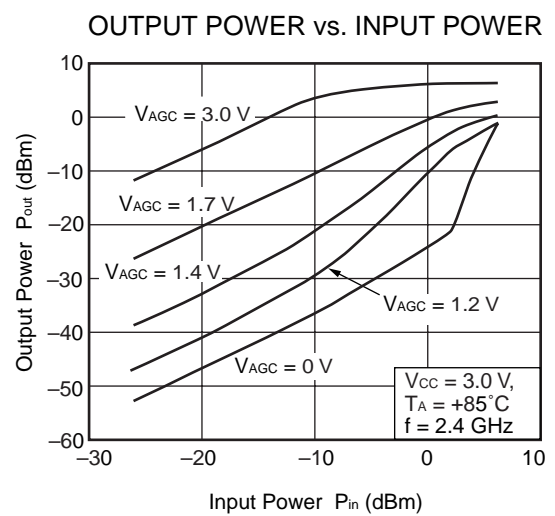
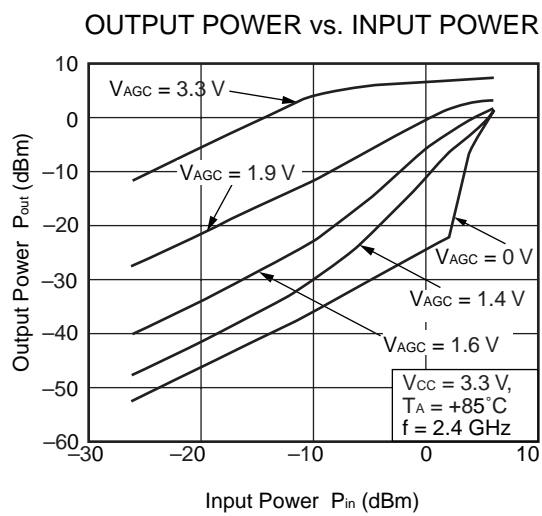
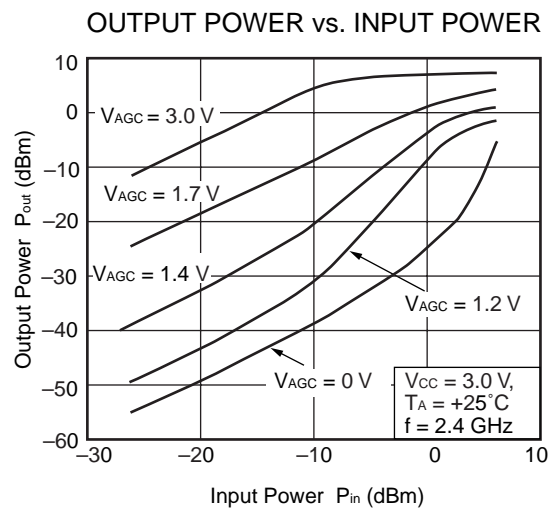
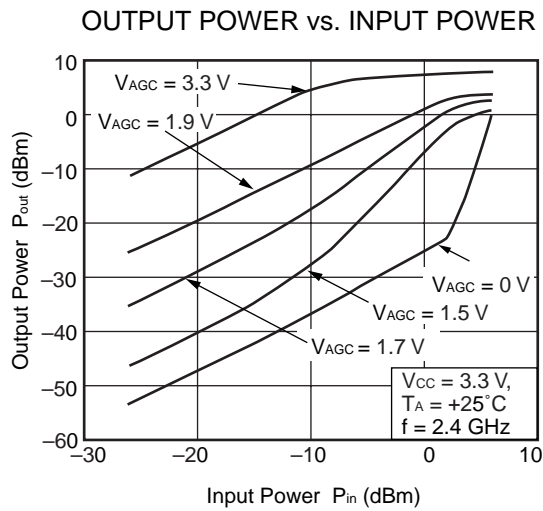
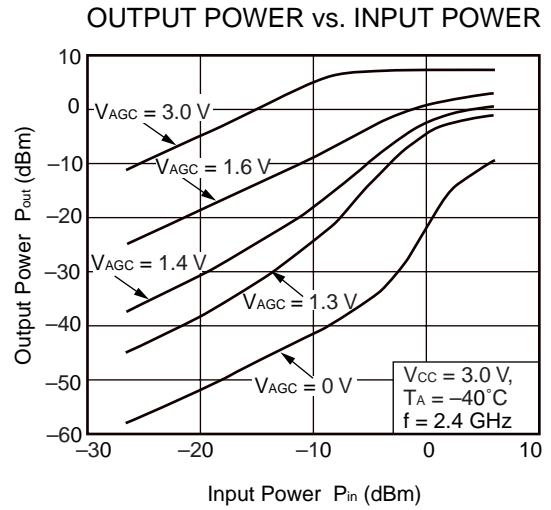
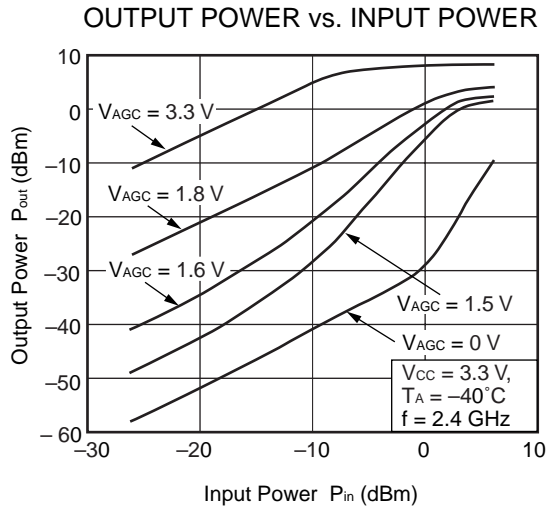
OUTPUT POWER vs. INPUT POWER



OUTPUT POWER vs. INPUT POWER

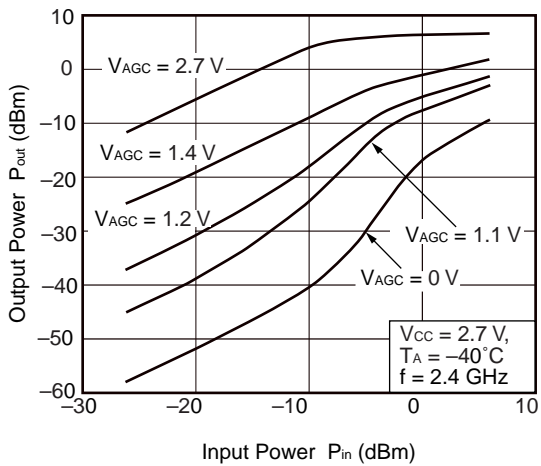


**Remark** The graphs indicate nominal characteristics.

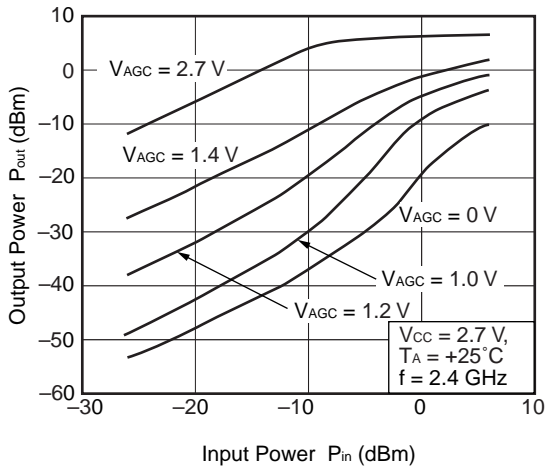


**Remark** The graphs indicate nominal characteristics.

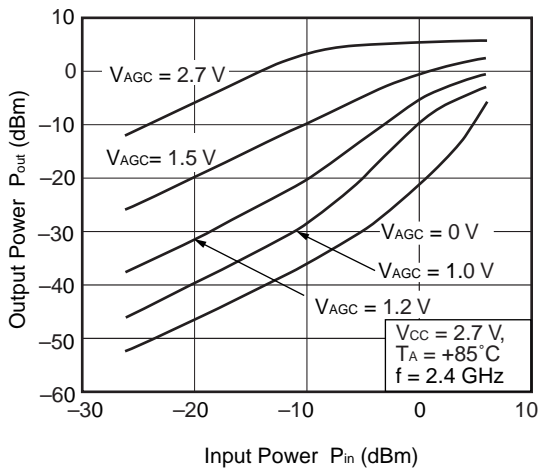
OUTPUT POWER vs. INPUT POWER



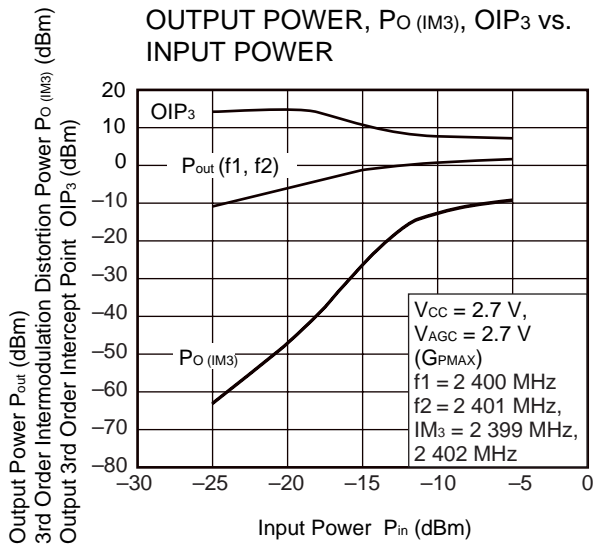
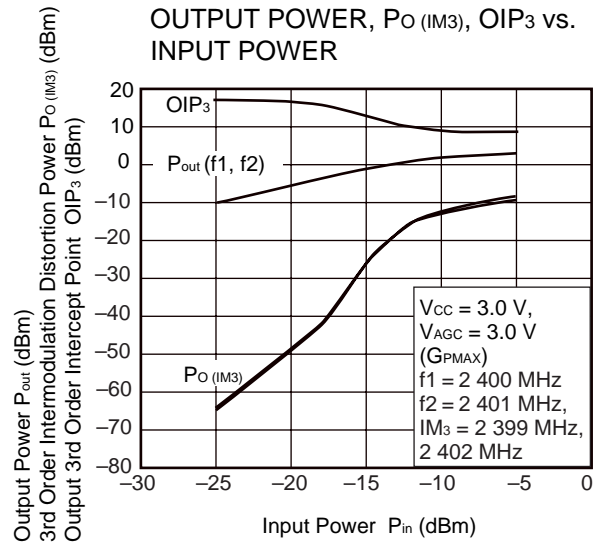
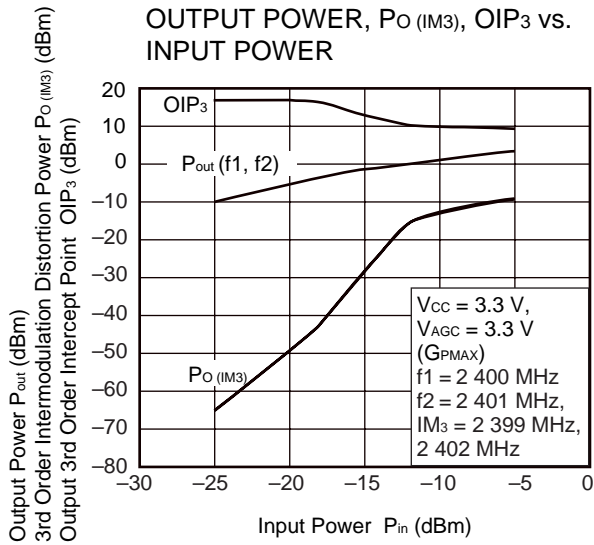
OUTPUT POWER vs. INPUT POWER



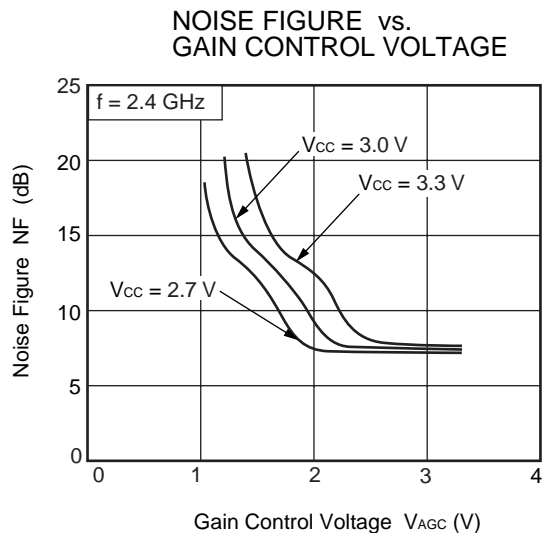
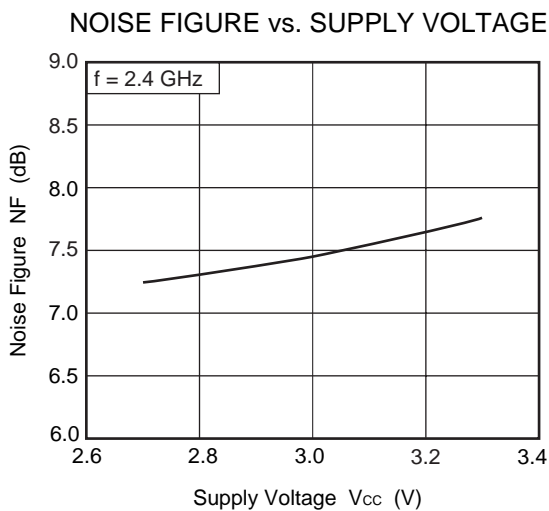
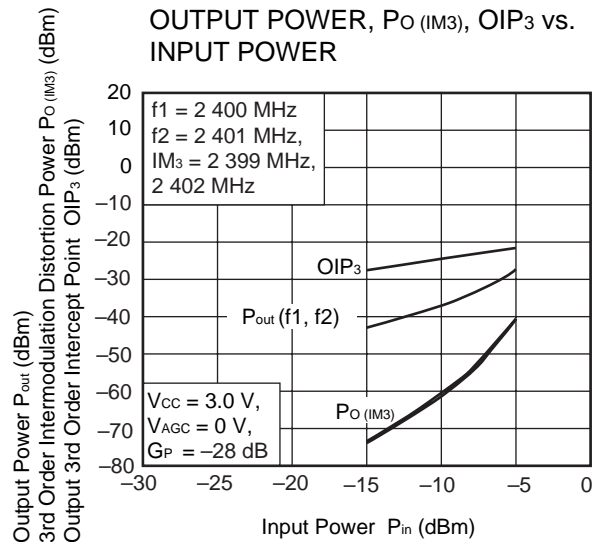
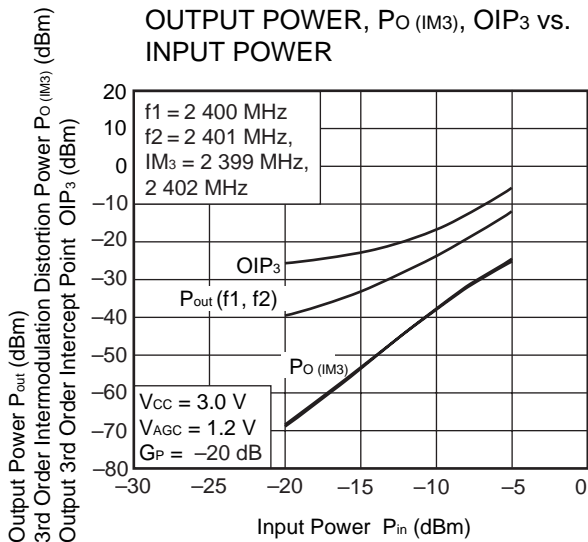
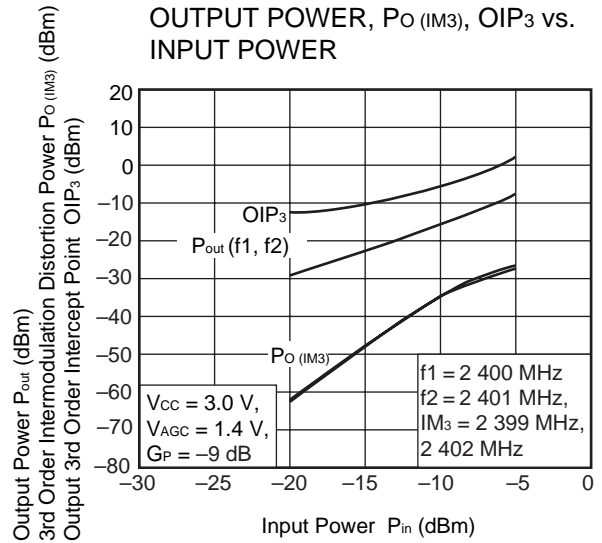
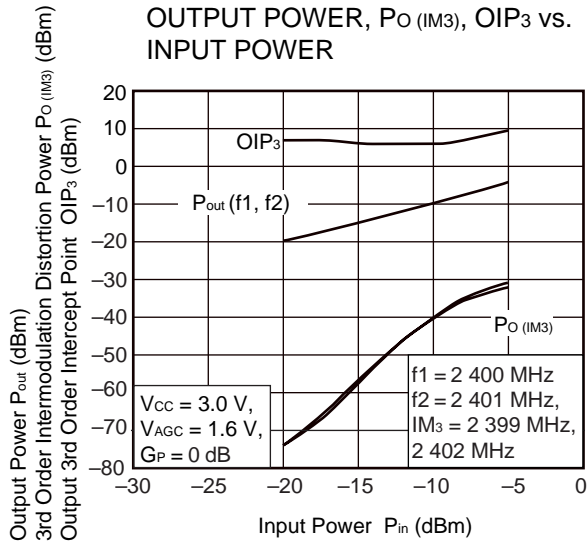
OUTPUT POWER vs. INPUT POWER



**Remark** The graphs indicate nominal characteristics.



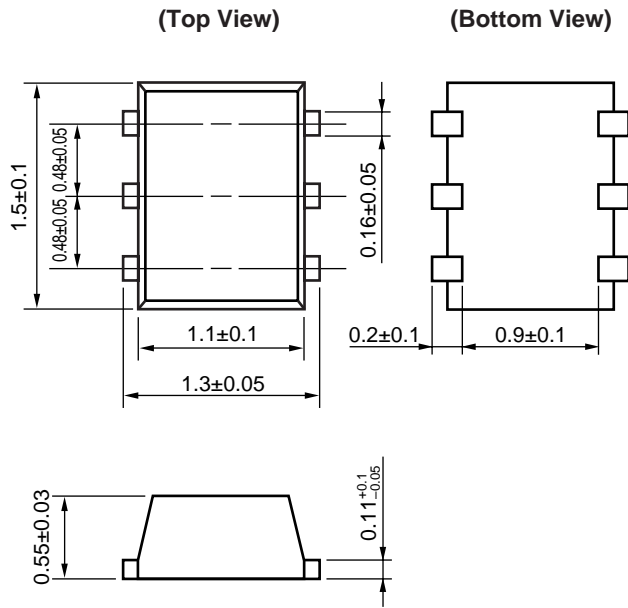
**Remark** The graphs indicate nominal characteristics.



**Remark** The graphs indicate nominal characteristics.

★ 7. PACKAGE DIMENSIONS

6-PIN LEAD-LESS MINIMOLD (1511 PKG) (UNIT: mm)



**8. NOTES ON CORRECT USE**

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as wide as possible to minimize ground impedance (to prevent undesired oscillation).  
All the ground pins must be connected together with wide ground pattern to decrease impedance difference.
- (3) The bypass capacitor should be attached to the V<sub>CC</sub> terminal.
- (4) Impedance matching circuit must be each externally attached to input and output ports.
- (5) The DC capacitor must be attached to input terminal.

**★ 9. RECOMMENDED SOLDERING CONDITIONS**

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

| Soldering Method | Soldering Conditions  | Condition Symbol |
|------------------|---|------------------|
| Infrared Reflow  | Peak temperature (package surface temperature) : 260°C or below<br>Time at peak temperature : 10 seconds or less<br>Time at temperature of 220°C or higher : 60 seconds or less<br>Preheating time at 120 to 180°C : 120±30 seconds<br>Maximum number of reflow processes : 3 times<br>Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below | IR260            |
| Wave Soldering   | Peak temperature (molten solder temperature) : 260°C or below<br>Time at peak temperature : 10 seconds or less<br>Preheating temperature (package surface temperature) : 120°C or below<br>Maximum number of flow processes : 1 time<br>Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below  | WS260            |
| Partial Heating  | Peak temperature (terminal temperature) : 350°C or below<br>Soldering time (per side of device) : 3 seconds or less<br>Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below   | HS350            |

**Caution Do not use different soldering methods together (except for partial heating).**



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 "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)  
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M8E 00.4-0110

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► For further information, please contact

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CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (\*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL’s understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

| Restricted Substance per RoHS | Concentration Limit per RoHS (values are not yet fixed) | Concentration contained in CEL devices |     |
|-------------------------------|---|--|-----|
|                               |   | -A                                     | -AZ |
| Lead (Pb)                     | < 1000 PPM  | Not Detected                           | (*) |
| Mercury                       | < 1000 PPM  | Not Detected                           |     |
| Cadmium                       | < 100 PPM   | Not Detected                           |     |
| Hexavalent Chromium           | < 1000 PPM  | Not Detected                           |     |
| PBB                           | < 1000 PPM  | Not Detected                           |     |
| PBDE                          | < 1000 PPM  | Not Detected                           |     |

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

**Important Information and Disclaimer:** Information provided by CEL on its website or in other communications concerning the substance content of its products represents knowledge and belief as of the date that it is provided. CEL bases its knowledge and belief on information provided by third parties and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. CEL has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. CEL and CEL suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall CEL’s liability arising out of such information exceed the total purchase price of the CEL part(s) at issue sold by CEL to customer on an annual basis.

See CEL Terms and Conditions for additional clarification of warranties and liability.

## Данный компонент на территории Российской Федерации

### Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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